

Ordering number: EN2076D

SANYO	No. 2076D	CMOS LSI
	LC6520C, 6522C, LC6520H, 6522H	
Single-Chip 4-Bit Microcomputers for Medium/Large-Scale Control-Oriented Applications		

The LC6520C/H are single-chip 4-bit microcomputers that contain a 4K-byte ROM, 1K-bit RAM, have 42 pins, and are fabricated using CMOS process technology. Besides 8 input/output common ports of 32 pins and an input port of 4 pins, the LC6520C/H have specific ports that are used to provide the interrupt function, 4-bit/8-bit serial input/output function, and burst pulse output function. All output ports are of the open drain type with a withstand voltage of 15 V and a drive current of 20 mA and have the option of containing a pull-up resistance bitwise.

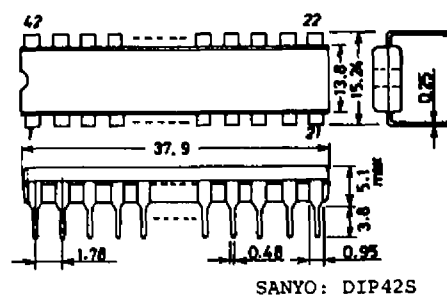
The LC6520C/H are the same as our LC6500 series in the basic architecture of the CPU and the instruction set, but are made more powerful in the stack level and the cycle time.

The LC6522C/H are the same as the LC6520C/H, except that they contain a 2k-byte ROM, 512-bit RAM.

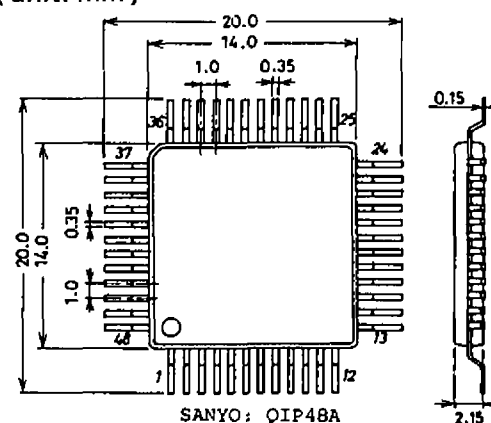
Features

- Instruction set with 80 instructions (Common to the LC6500 series)
- ROM/RAM
 - : 4096 bytes/1024 bits (LC6520C/H)
 - : 2048 bytes/512 bits (LC6522C/H)
- Instruction cycle time: 6 μ s (C version, $V_{DD} = 3$ to 5.5V)
2.77 μ s (C version, $V_{DD} = 4$ to 5.5V)
9.92 μ s (H version, $V_{DD} = 4.5$ to 5.5V)
- Serial input/output interface x 1 (4 bits/8 bits program-selectable)
- I/O ports
 - Input port: 4 pins
 - Input/output common ports: 32 pins
 - Input • input/output withstand voltage: 15 V max (all input • input/output ports)
 - Output current: 20 mA max (all output ports)
 - Pull-up resistance: May be contained bitwise by option. (All output ports)
 - Output level during reset: For ports C, D, output (H or L) during reset may be specified portwise by option.

Package Dimensions 3025B-D42SIC
(unit: mm)



Package Dimensions 3052A-Q48AIC
(unit: mm)

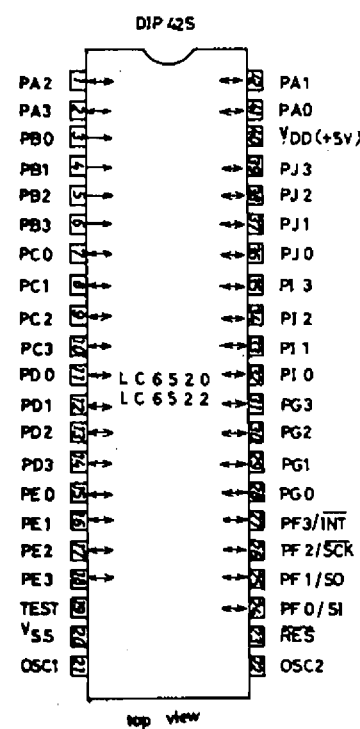


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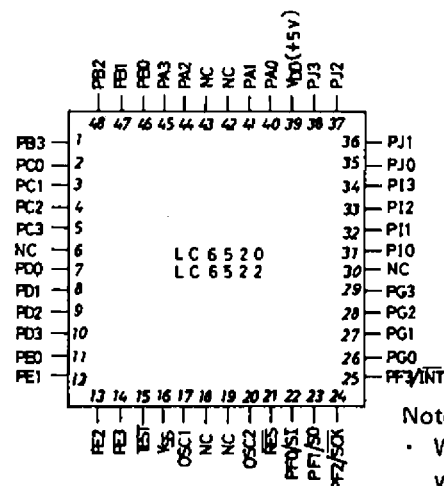
5202HK / 4209TA / 7137KI / 4176KI, TS No.2076-1/29

- Interrupt function
 - Timer interrupt: 1
 - INT pin or serial I/O interrupt: 1
- Stack level: 8 levels (common with interrupt)
- Timer: 4-bit prescaler + 8-bit programmable timer
- Burst pulse (64 x cycle time, duty 50%) output function
- Oscillator option
 - Circuit mode: Ceramic mode, RC mode, external clock mode (200 kHz to 4.2 MHz)
 - (Xtal OSC constants are being checked.)
 - Predivider option: 1/1, 1/3, 1/4
- Standby function: Standby function provided by the HALT instruction
- Supply Voltage: 3 to 5.5 V (C version)
 - 4.5 to 5.5 V (H version)
- Package: DIP42 shrink type, QIP48

Pin Assignment



QIP48



Note)

- When mounting the QIP version on the board, do not dip it in solder.
- Nothing must be connected to NC pin.

Pin Name

OSC1, OSC2: RC, ceramic resonator, or X'tal for OSC
 INT: Interrupt
 RES: Reset
 PA0-3: Input/output common port
 PB0-3: Input port
 PC0-3: Input/output common port
 PD0-3: Input/output common port
 PE0-3: Input/output common port
 PF0-3: Input/output common port
 PG0-3: Input/output common port
 PI0-3: Input/output common port
 PJ0-3: Input/output common port
 SCK: Serial Input/output port
 SI: Serial Input/output port
 TEST: Test

Pin Description

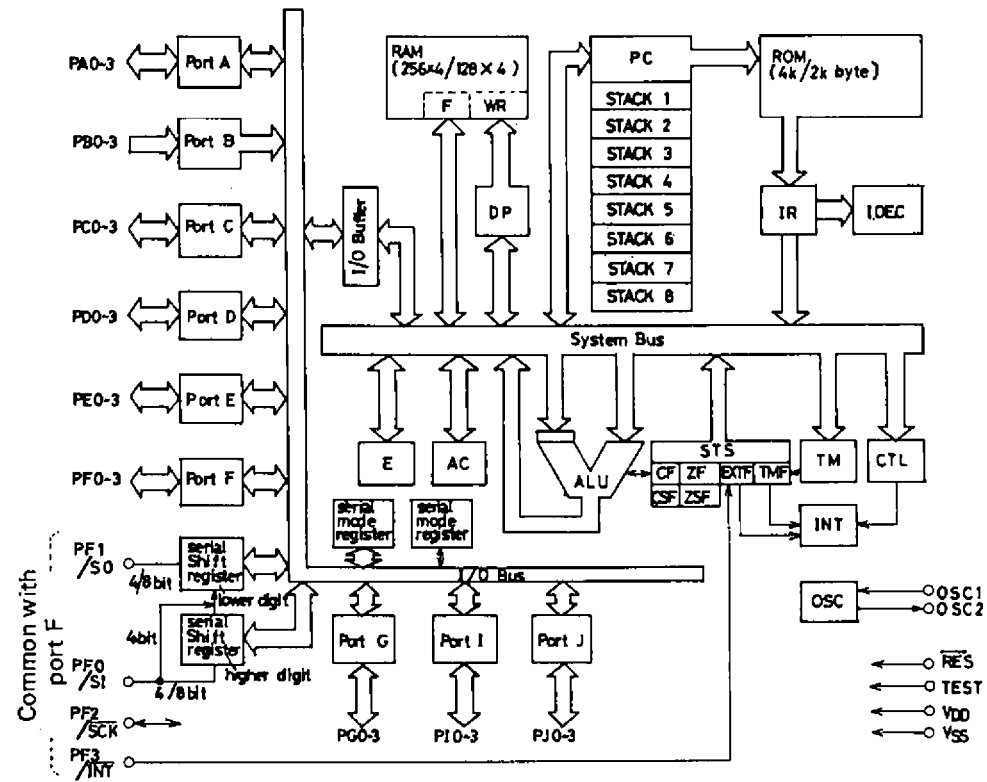
Pin Name	Pins	I/O	Functions	Options	During Reset
V _{DD} V _{SS}	1 1		Power supply		
OSC1	1	Input	<ul style="list-style-type: none"> Pin for externally connecting R, C or a ceramic resonator for system clock generation 	(1) External clock input (2) 2-pin RC OSC (3) 2-pin ceramic resonator OSC	
OSC2	1	Output	<ul style="list-style-type: none"> For the external clock mode, the OSC2 pin is open. 	(4) Predivider option 1. No. predivider 2. 1/3 predivider 3. 1/4 predivider	
PA ₀ PA ₁ PA ₂ PA ₃	4	Input/output	<ul style="list-style-type: none"> Input/output common port A₀ to 3. 4-bit input (IP instruction) 4-bit output (OP instruction) Single-bit decision (BP, BNP instructions) Single-bit set/reset (SPB, RPB instructions) Standby is controlled by the PA₃ (or PA₀ to 3). The PA₃ (or PA₀ to 3) pin must be free from chattering during the HALT instruction execution cycle. 	(1) Open drain type output (2) With pull-up resistance (1), (2): Specified bit by bit.	<ul style="list-style-type: none"> "H" output (Output Nch transistor OFF)
PB ₀ PB ₁ PB ₂ PB ₃	4	Input	<ul style="list-style-type: none"> Input Port B₀ to 3 4-bit input (IP instruction) Single-bit decision (BP, BNP instructions) 		
PC ₀ PC ₁ PC ₂ PC ₃	4	Input/output	<ul style="list-style-type: none"> Input/output common port C₀ to 3. The functions are the same as for the PA₀ to 3. (Note) Output ("H" or "L") during reset may be specified by option. <p>(Note) No standby control function is provided.</p>	(1) Open drain type output (2) With pull-up resistance (3) Output during reset: "H" (4) Output during reset: "L" <ul style="list-style-type: none"> (1), (2): Specified bit by bit. (3), (4): Specified in a group of 4 bits. 	<ul style="list-style-type: none"> "H" output "L" output (Option-selectable)
PD ₀ PD ₁ PD ₂ PD ₃	4	Input/output	<ul style="list-style-type: none"> Input/output common port D₀ to 3 The functions, options are the same as for the PC₀ to 3. 	Same as for the PC ₀ to 3.	Same as for the PC ₀ to 3.
PE ₀ PE ₁ PE ₂ PE ₃	4	Input/output	<ul style="list-style-type: none"> Input/output common port E₀ to 3 4-bit input (IP instruction) 4-bit output (OP instruction) Single-bit decision (BP, BNP instructions) Single-bit set/reset (SPB, RPB instructions) PE₀: With burst pulse (64T_{cyc}) output function 	(1) Open drain type output (2) With pull-up resistance (1), (2): Specified bit by bit.	<ul style="list-style-type: none"> "H" output (Output Nch transistor OFF)

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Pin Name	Pins	I/O	Functions	Options	During Reset
PF ₀ /SI PF ₁ /SO PF ₂ /SCK PF ₃ /INT	4	Input/output	<ul style="list-style-type: none"> Input/output port F₀ to 3 The functions, options are the same as for the PE₀ to 3. However, no burst pulse output function is provided. PF₀ to 3: Also used for serial interface, INT input. Program-selectable. 4 bits/8 bits of serial input/output: Program-selectable SI: Serial input port SO: Serial output port SCK: Serial clock input/output INT: Interrupt request input 	Same as for the PE ₀ to 3.	Same as for the PE ₀ to 3. Serial port: Disable Interrupt source: INT
PG ₀ PG ₁ PG ₂ PG ₃	4	Input/output	<ul style="list-style-type: none"> Input/output common port G₀ to 3 The functions, options are the same as for the PE₀ to 3. However, no burst pulse output function is provided. 	Same as for the PE ₀ to 3.	Same as for the PE ₀ to 3.
PI ₀ PI ₁ PI ₂ PI ₃	4	Input/output	<ul style="list-style-type: none"> Input/output common port I₀ to 3 The functions, options are the same as for the PG₀ to 3. 	Same as for the PG ₀ to 3.	Same as for the PG ₀ to 3.
PJ ₀ PJ ₁ PJ ₂ PJ ₃	4	Input/output	<ul style="list-style-type: none"> Input/output common port J₀ to 3 The functions, options are the same as for the PG₀ to 3. 	Same as for the PG ₀ to 3.	Same as for the PG ₀ to 3.
RES	1	Input	<ul style="list-style-type: none"> System reset input For power-up reset, C is connected externally. For reset start, "L" level is applied for 4 clock cycles or more. 		
TEST	1	Input	<ul style="list-style-type: none"> LSI test pin Normally connected to V_{SS} 		

System Block Diagram



RAM:	Data memory	ROM:	Program memory
F:	Flag	PC:	Program counter
WR:	Working register	INT:	Interrupt control
AC:	Accumulator	IR:	Instruction register
ALU:	Arithmetic and logic unit	I.DEC:	Instruction decoder
DP:	Data pointer	CF, CSF:	Carry flag, carry save flag
E:	E register	ZF, ZSF:	Zero flag, zero save flag
CTL:	Control register	EXTF:	External interrupt request flag
OSC:	Oscillator	TMF:	Internal interrupt request flag
TM:	Timer		
STS:	Status register		

Oscillator Circuit Option

Option Name	Circuit	Conditions, etc.
1. External Clock		<ul style="list-style-type: none"> Input: Schmitt type
2. 2-pin RC OSC		<ul style="list-style-type: none"> Input: Schmitt type
3. Ceramic Resonator OSC		

• **Predivider Option**

Option Name	Circuit	Conditions, etc.
1. No predivider		<ul style="list-style-type: none"> Applicable to all of 3 OSC options. The OSC frequency, external clock do not exceed 1444 kHz. (LC6520C, LC6522C) The OSC frequency, external clock do not exceed 4330 kHz. (LC6520H, LC6522H) Refer to Table of OSC, Predivider Option (Table 2).
2. 1/3 predivider		<ul style="list-style-type: none"> Applicable to only 2 options of external clock, ceramic resonator OSC. The OSC frequency, external clock do not exceed 4330 kHz. Refer to Table of OSC, Predivider Option (Table-2).
3. 1/4 predivider		<ul style="list-style-type: none"> Applicable to only 2 options of external clock, ceramic resonator OSC. The OSC frequency, external clock do not exceed 4330 kHz. Refer to table of OSC, Predivider Option (Table 2).

Options of Ports C, D Output Level during Reset
For input/output common ports C, D, either of the following two output levels may be selected in a group of 4 bits during reset by option.

Option Name	Conditions, etc.
1. Output during reset: "H" level	All of 4 bits of ports C, D
2. Output during reset: "L" level	All of 4 bits of ports C, D

Options of Port Output Configuration
For each input/output-common port, either of the following two output configurations may be selected by option (bitwise).

Option Name	Circuit	Conditions, etc.
1. Open drain type output		
2. Output with pull-up resistance		

Development Support

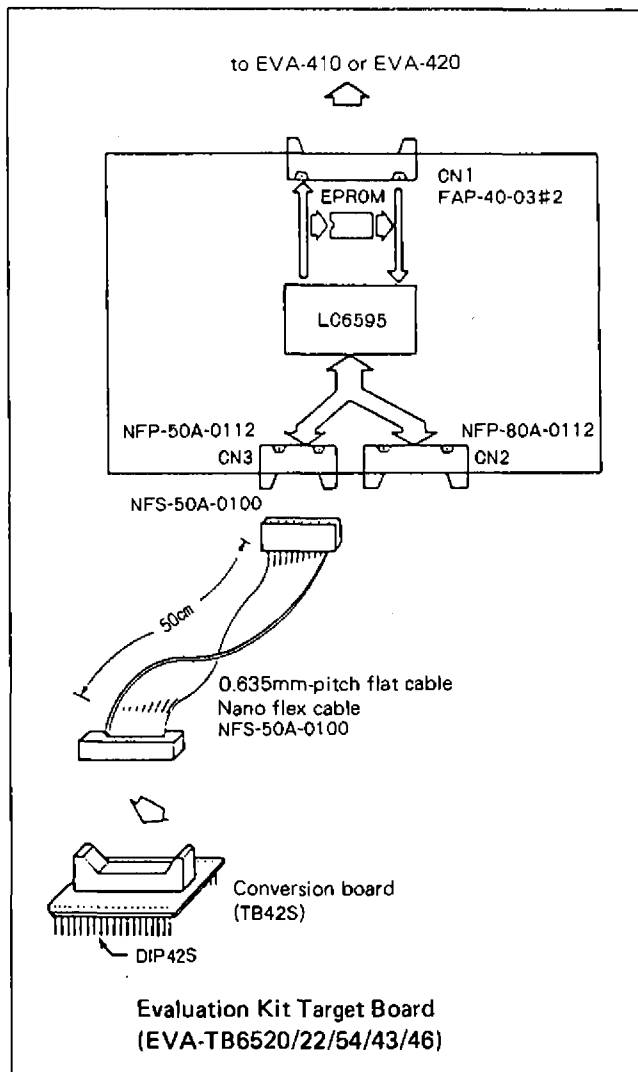
The following are available to support the LC6520, LC6522 program development.

- (1) User's Manual
"LC6554 Series User's Manual" No. E21B. (Issued in December, 1987)
- (2) Development Tool Manual
For the EVA-410 system, refer to the description of Development Support Tools in "LC6554 Series User's Manual". For the EVA-800 system, refer to "EVA-800-LC6554 Series Development Tool Manual".
- (3) Development Tools
 - 1) For program development (EVA-410 system)
 - i. MS-DOS host computer system (Note 1)
 - ii. MS-DOS base cross assembler (LC65S.EXE)
 - iii. Evaluation kit (EVA-410C or EVA-420)
 - iv. Evaluation kit target board (EVA-TB6520/22/54/43/46), evaluation chip (LC6595)
 - 2) For program evaluation
 - i. Piggyback (LC65PG20/22), with socket for conversion of number of piggyback pins

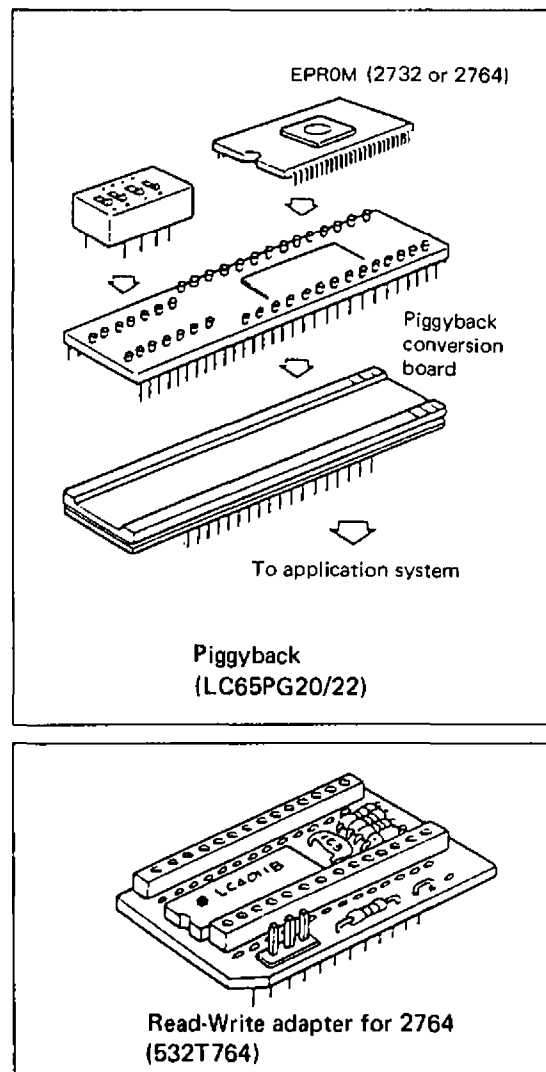
Note. For notes on program evaluation, do not fail to refer to "5-3-1. Notes on when evaluating programs for the LC6520/22" in "LC6554 Series User's Manual".

Appearance of Application Development Tools

EVA-410 System



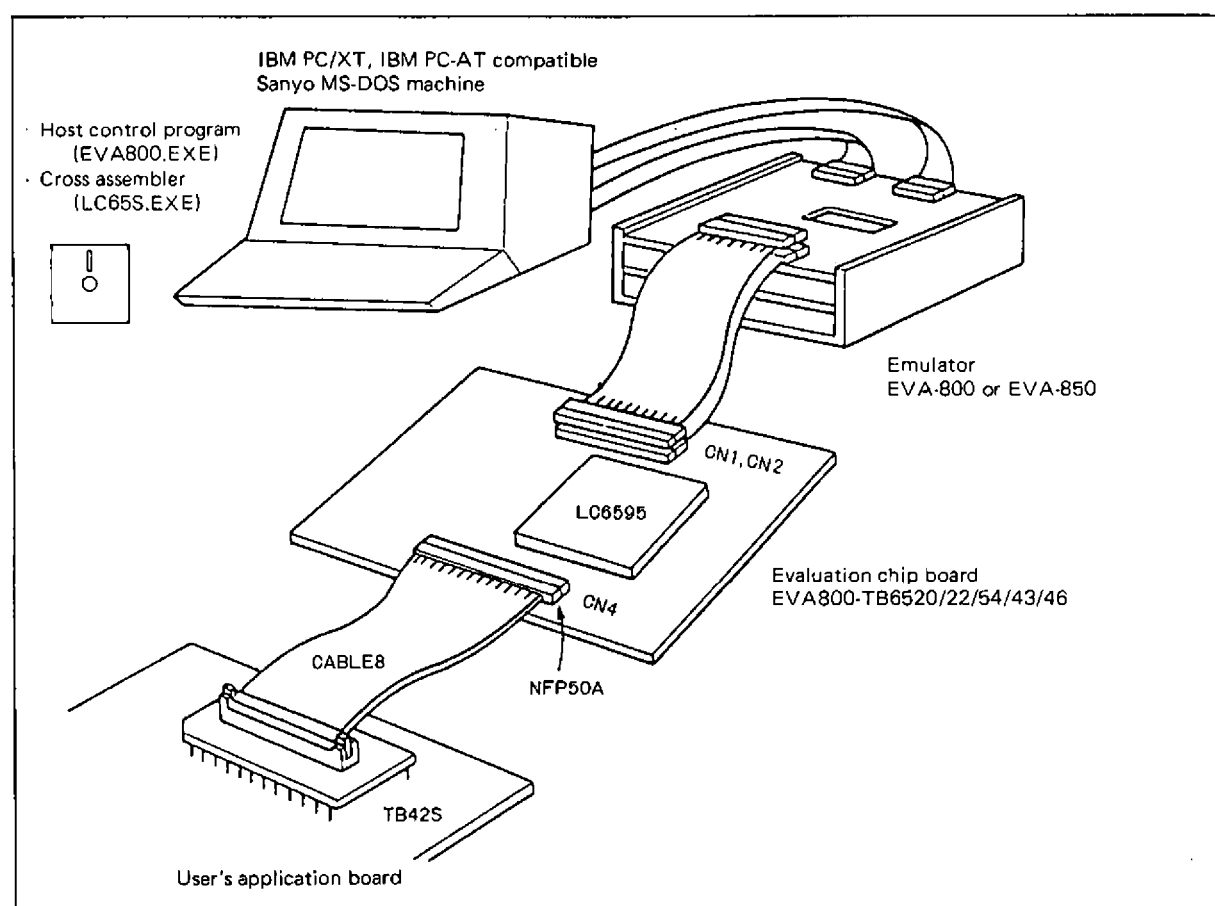
Piggyback



- 3) For program development (EVA-800 system)
 - i. IBM PC/XT, IBM PC-AT (Note 1) compatible Sanyo MS-DOS machine
 - ii. Cross assemblerMS-DOS base cross assembler: (LC65S.EXE)
 - iii. Host control program: (EVA800.EXE)
 - iv. Evaluation chip: LC6595
 - v. Emulator : EVA-800 or EVA-850 control board and evaluation chip board (Note 2)

Appearance of Development Support System

EVA-800 System



(Note 1) IBM PC/XT, IBM PC-AT: Products of IBM Corporation

MS-DOS: Trademark of Microsoft Corporation

(Note 2) The EVA-800 is a general term for emulator. A suffix (A, B ...) is added at the end of EVA-800 as the EVA-800 is improved to be a newer version. Do not use the EVA-800 with no suffix added.

Main Specifications of the LC6520C, 6522C

Absolute Maximum Ratings/ $T_a = 25^\circ\text{C}$, $V_{SS} = 0\text{V}$

				unit
Maximum Supply Voltage	$V_{DD\text{ max}}$	V_{DD}	-0.3 to +7.0	V
Output Voltage	V_o	OSC2	Allowable up to voltage generated	V
Input Voltage	V_i (1)	OSC1 (Note 1)	-0.3 to $V_{DD}+0.3$	V
	V_i (2)	TEST, RES	-0.3 to $V_{DD}+0.3$	V
	V_i (3)	PB0 to 3	-0.3 to +15	V
Input/Output Voltage	V_{IO} (1)	Port of OD type	-0.3 to +15	V
	V_{IO} (2)	Port of PU type	-0.3 to $V_{DD}+0.3$	V
Peak Output Current	I_{OP}	Input/output port	-2 to +20	mA
Average Output Current	I_{OA}	Input/output port:	-2 to +20	mA
		Per pin over the period of 100 msec.		
	ΣI_{OA} (1)	Total current of PA0 to 3, PC0 to 3, PD0 to 3 and PE0 to 3 (Note 2)	-30 to +140	mA
	ΣI_{OA} (2)	Total current of PF0 to 3, PG0 to 3, PI0 to 3 and PJ0 to 3 (Note 2)	-30 to +140	mA
Allowable Power Dissipation	$P_d\text{ max}$ (1)	DIP package, $T_a = -30$ to $+70^\circ\text{C}$	600	mW
	$P_d\text{ max}$ (2)	QIP package, $T_a = -30$ to $+70^\circ\text{C}$	400	mW
Operating Temperature	T_{opr}		-30 to +70	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +125	$^\circ\text{C}$

Allowable Operating Conditions/ $T_a = -30$ to $+70^\circ\text{C}$, $V_{SS} = 0\text{V}$, $V_{DD} = 3.0$ to 5.5V

			min	typ	max	unit
Operating Supply Voltage	V_{DD}	V_{DD}	3.0		5.5	V
Standby Supply Voltage	V_{st}	V_{DD} : RAM, resistor hold (Note 3)	1.8		5.5	V
"H"-Level Input Voltage	V_{IH} (1)	Port of OD type, PB0 to 3: Output Nch Tr OFF	$0.7V_{DD}$		+13.5	V
	V_{IH} (2)	Port of PU type: Output Nch Tr OFF	$0.7V_{DD}$		V_{DD}	V
	V_{IH} (3)	\overline{SCK} , SI, \overline{INT} of OD type: Output Nch Tr OFF	$0.8V_{DD}$		+13.5	V
	V_{IH} (4)	\overline{SCK} , SI, \overline{INT} of PU type: Output Nch Tr OFF	$0.8V_{DD}$		V_{DD}	V
	V_{IH} (5)	\overline{RES}	$0.8V_{DD}$		V_{DD}	V
	V_{IH} (6)	OSC1: External clock mode	$0.8V_{DD}$		V_{DD}	V
"L"-Level Input Voltage	V_{IL} (1)	PORT: $V_{DD} = 4$ to 5.5V , Output Nch Tr OFF	V_{SS}		$0.3V_{DD}$	V
	V_{IL} (2)	PORT: Output Nch Tr OFF	V_{SS}		$0.25V_{DD}$	V
	V_{IL} (3)	\overline{INT} , \overline{SCK} , SI: $V_{DD} = 4$ to 5.5V Output Nch Tr OFF	V_{SS}		$0.25V_{DD}$	V
	V_{IL} (4)	\overline{INT} , \overline{SCK} , SI: Output Nch Tr OFF	V_{SS}		$0.2V_{DD}$	V
	V_{IL} (5)	OSC1: $V_{DD} = 4$ to 5.5V , External clock mode	V_{SS}		$0.25V_{DD}$	V
	V_{IL} (6)	OSC1: External clock mode	V_{SS}		$0.2V_{DD}$	V
	V_{IL} (7)	TEST: $V_{DD} = 4$ to 5.5V	V_{SS}		$0.3V_{DD}$	V
	V_{IL} (8)	TEST	V_{SS}		$0.25V_{DD}$	V
	V_{IL} (9)	\overline{RES} : $V_{DD} = 4$ to 5.5V	V_{SS}		$0.25V_{DD}$	V
	V_{IL} (10)	\overline{RES}	V_{SS}		$0.2V_{DD}$	V
Operating Frequency (Cycle Time)	f_{op}			See Table 2.		
	(T_{cyc})	$(V_{DD} = 4.0$ to $5.5\text{V})$	(2.77) (6.0)		(20) (20)	(μs) (μs)

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LC6520C, 6520H, 6522C, 6522H

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External Clock Conditions (When the external clock or 2-pin RC OSC option is selected)			min	typ	max	unit
Frequency	f_{ext}	OSC1: Fig. 1		See Table 2.		
Pulse Width	t_{extH}	OSC1: $V_{DD} = 4$ to 5.5V, Fig. 1	90			ns
	t_{extL}	OSC1: Fig. 1	180			ns
Rise/Fall Time	t_{extR}	OSC1: $V_{DD} = 4$ to 5.5V, Fig. 1			30	ns
	t_{extF}	OSC1: Fig. 1			100	ns
Oscillation Guaranteed Constants						
2-Pin RC Oscillation	C_{ext}	OSC1, OSC2: $V_{DD} = 4$ to 5.5V, Fig. 2		220±5%		pF
	R_{ext}	OSC1, OSC2: $V_{DD} = 4$ to 5.5V, Fig. 2		6.8±1%		kΩ
	C_{ext}	OSC1, OSC2: Fig. 2		270±5%		pF
	R_{ext}	OSC1, OSC2: Fig. 2		15±1%		kΩ
Ceramic Resonator Oscillation		Fig. 3		See Table 1.		
Electrical Characteristics/ $T_a = -30$ to $+70^{\circ}C$, $V_{SS} = 0V$, $V_{DD} = 3.0$ to 5.5V						
"H"-Level Input Current	I_{IH} (1)	Port of open drain type, PB_0 to 3: Output Nch Tr OFF, Including OFF leakage current of Nch Tr, $V_{IN} = +13.5V$			+5.0	μA
"L"-Level Input Current	I_{IH} (2)	OSC1: External clock mode, $V_{IN} = V_{DD}$			+1.0	μA
	I_{IL} (1)	Port of open drain type, PB_0 to 3: Output Nch Tr OFF, $V_{IN} = V_{SS}$	-1.0			μA
	I_{IL} (2)	Port with pull-up resistance: Output Nch Tr OFF, $V_{IN} = V_{SS}$	-1.3	-0.35		mA
	I_{IL} (3)	RES: $V_{IN} = V_{SS}$	-45	-10		μA
	I_{IL} (4)	OSC1: External clock mode, $V_{IN} = V_{SS}$	-1.0			μA
"H"-Level Output Voltage	V_{OH} (1)	Port with pull-up resistance: $V_{DD} = 4$ to 5.5V, $I_{OH} = -50 \mu A$	$V_{DD}-1.2$			V
	V_{OH} (2)	Port with pull-up resistance: $I_{OH} = -10 \mu A$	$V_{DD}-0.5$			V
"L"-Level Output Voltage	V_{OL} (1)	Port: $V_{DD} = 4$ to 5.5V, $I_{OL} = 10$ mA			1.5	V
	V_{OL} (2)	Port: $I_{OL} = 1$ mA, When I_{OL} of each port is 1 mA or less.			0.5	V
Hysteresis Voltage	V_{Hys}	RES, INT, SCR, SI, OSC1 of Schmitt type (Note 6)	0.1 V_{DD}			V
Current Dissipation						
2-Pin RC Oscillation	Operation mode, Output Nch Tr OFF, Port = V_{DD}					
	I_{DDOP} (1)	V_{DD} : $V_{DD} = 4$ to 5.5V, Fig. 2 $f_{osc} = 750$ kHz typ	2		5	mA
Ceramic Resonator Oscillation	I_{DDOP} (2)	V_{DD} : Fig. 2 $f_{osc} = 350$ kHz typ	1.5		4.5	mA
	I_{DDOP} (3)	V_{DD} : Fig. 3 $V_{DD} = 4$ to 5.5V, 4MHz, 1/3 predivider	5		10	mA
	I_{DDOP} (4)	V_{DD} : Fig. 3 $V_{DD} = 4$ to 5.5V, 4MHz, 1/4 predivider	5		10	mA
	I_{DDOP} (5)	V_{DD} : Fig. 3 400kHz	1.5		4	mA
External Clock	I_{DDOP} (6)	V_{DD} : $V_{DD} = 4$ to 5.5V, Fig. 3 800kHz	2		5	mA
	I_{DDOP} (7)	V_{DD} : 200 kHz to 667 kHz, 1/1 predivider	2		5	mA
	I_{DDOP} (8)	600 kHz to 2000 kHz, 1/3 predivider	3	10	mA	
		800 kHz to 2667 kHz, 1/4 predivider				
V_{DD} : $V_{DD} = 4$ to 5.5V, 200 kHz to 1444 kHz, 1/1 predivider 600 kHz to 4330 kHz, 1/3 predivider 800 kHz to 4330 kHz, 1/4 predivider						
Standby Mode	I_{DDSt}	V_{DD} : $V_{DD} = 5.5V$ (Output Nch Tr OFF, V_{DD} : $V_{DD} = 3V$ (Port = V_{DD}	0.05		10	μA
			0.025		5	μA

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LC6520C,6520H,6522C,6522H

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			min	typ	max	unit
Oscillation Characteristics						
Ceramic Resonator Oscillation						
Oscillation Frequency	f _{CFOSC} (Note 4)	OSC1, OSC2: Fig. 3 f _o = 400 kHz	392	400	408	kHz
		OSC1, OSC2: V _{DD} = 4 to 5.5V, Fig. 3 f _o = 800 kHz	784	800	816	kHz
		OSC1, OSC2: V _{DD} = 4 to 5.5V, Fig. 3 f _o = 3 MHz, 1/3 predivider, 1/4 predivider	2940	3000	3060	kHz
		OSC1, OSC2: V _{DD} = 4 to 5.5V, Fig. 3 f _o = 4 MHz, 1/3 predivider, 1/4 predivider	3920	4000	4080	kHz
Oscillation Stabilizing Period	t _{CFS}	Fig. 4 f _o = 400 kHz			10	ms
		V _{DD} = 4 to 5.5V, Fig. 4 f _o = 4 MHz, 3 MHz, 800 kHz			10	ms
2-Pin RC Oscillation						
Oscillation Frequency	f _{MOSC} (1)	OSC1, OSC2: V _{DD} = 4 to 5.5V, Fig. 2, C _{ext} = 220 pF±5%, R _{ext} = 6.8 kΩ±1%	515	750	1156	kHz
	f _{MOSC} (2)	OSC1, OSC2: Fig. 2, C _{ext} = 270 pF±5%, R _{ext} = 15 kΩ±1%	222	350	609	kHz
Pull-up Resistance						
I/O Port Pull-up Resistance	R _{pp}	Port of PU type: V _{DD} = 5V		14		kΩ
External Reset Characteristics						
"H"-Level Threshold	V _{tH}		0.5V _{DD}	0.8V _{DD}		V
"L"-Level Threshold	V _{tL}		0.2V _{DD}	0.5V _{DD}		V
Reset Time	T _{RST}			See Fig. 5.		
Pin Capacitance	CP	f = 1 MHz, Other than pins to be tested, V _{IN} = V _{SS}		10		pF
Serial Clock						
Input Clock Cycle Time	t _{CKCY} (1)	\overline{SCK} : V _{DD} = 4 to 5.5V, Fig. 6	3.0			μs
		\overline{SCK}	12.0			μs
Output Clock Cycle Time	t _{CKCY} (2)	\overline{SCK} (T _{CYC} = 4 x System clock period), Fig. 6		64 x T _{CYC}		μs
Input Clock "L"-Level Pulse Width	t _{CKL} (1)	\overline{SCK} : V _{DD} = 4 to 5.5V, Fig. 6	1.0			μs
		\overline{SCK}	4.0			μs
Output Clock "L"-Level Pulse Width	t _{CKL} (2)	\overline{SCK} , Fig. 6		32 x T _{CYC}		μs
Input Clock "H"-Level Pulse Width	t _{CKH} (1)	\overline{SCK} : V _{DD} = 4 to 5.5V, Fig. 6	1.0			μs
		\overline{SCK}	4.0			μs
Output Clock "H"-Level Pulse Width	t _{CKH} (2)	\overline{SCK} : Fig. 6		32 x T _{CYC}		μs
Serial Input						
Data Setup Time	t _{ICK}	SI: Specified for ↑ of \overline{SCK} , Fig. 6	0.5			μs
Data Hold Time	t _{CKI}	SI: Specified for ↑ of \overline{SCK} , Fig. 6	0.5			μs
Serial Output						
Output Delay Time	t _{CKO}	SO: V _{DD} = 4 to 5.5V, Specified for ↓ of \overline{SCK} , Nch OD only: External 1 kohm, external 50 pF, Fig. 6			0.5	μs
		SO			2.0	μs
Pulse Output						
Period	t _{PCY}	PE0: T _{CYC} = 4 x System clock period, Nch OD only: External 1 kohm, external 50 pF, Fig. 7		64 x T _{CYC}		μs
"H"-Level Pulse Width	t _{pH}	PE0:	32 x T _{CYC} ±10%			μs
"L"-Level Pulse Width	t _{pL}	PE0:	32 x T _{CYC} ±10%			μs

Note 1: When oscillated internally under the oscillating conditions in Fig. 3, up to the oscillation amplitude generated is allowable.

Note 2: Average over the period of 100 msec.

Note 3: Operating supply voltage V_{DD} must be held until the standby mode is entered after the execution of the HALT instruction.

The PA3 (or PA0 to 3) pin must be free from chattering during the HALT instruction execution cycle.

Note 4: f_{CFOSC} represents an oscillatable frequency. There is a tolerance of approximately 1% between the center frequency at the ceramic mode and the nominal value presented by the ceramic resonator supplier. For details, refer to the specification for the ceramic resonator.

Note 5: When mounting the QIP version on the board, do not dip it in solder.

Note 6: The OSC1 becomes the Schmitt type when the OSC option is the 2-pin RC OSC or external clock OSC.

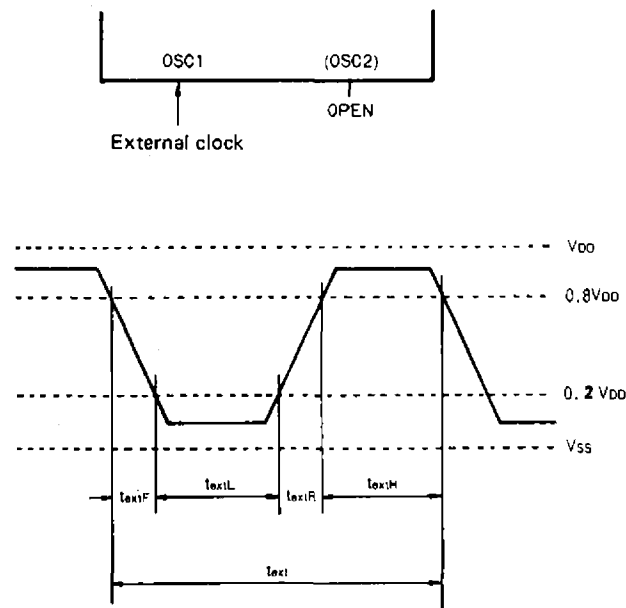


Fig. 1 External Clock Input Waveform

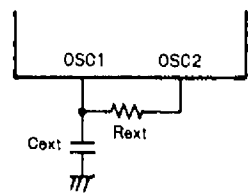


Fig. 2 2-Pin RC Oscillation Circuit

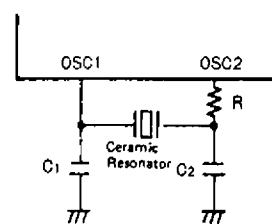


Fig. 3 Ceramic Resonator Oscillation Circuit

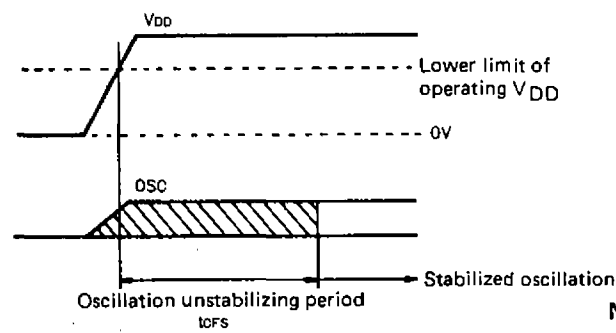


Fig. 4 Oscillation Stabilizing Period

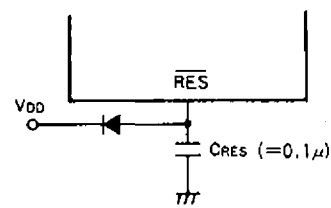


Fig. 5 Reset Circuit

Note 7: When the rise time of the power supply is 0, the reset time becomes 10 ms to 100 ms at C_{RES} = 0.1 μF. If the rise time of the power supply is long, the value of C_{RES} must be increased so that the reset time becomes 10 ms or greater.

4MHz (Murata) CSA4.00MG	C1	33pF ± 10%	800kHz (Murata) CSB800D CSB800K	C1	220pF ± 10%
	C2	33pF ± 10%		C2	220pF ± 10%
	R	0Ω		R	0Ω
4MHz (Kyocera) KBR4.0MS	C1	33pF ± 10%	800kHz (Kyocera) KBR800H	C1	150pF ± 10%
	C2	33pF ± 10%		C2	150pF ± 10%
	R	0Ω		R	0Ω
3MHz (Murata) CSA3.00MG	C1	33pF ± 10%	400kHz (Murata) CSB400P	C1	470pF ± 10%
	C2	33pF ± 10%		C2	470pF ± 10%
	R	0Ω		R	0Ω
3MHz (Kyocera) KBR3.0MS	C1	47pF ± 10%	400kHz (Kyocera) KBR400B	C1	330pF ± 10%
	C2	47pF ± 10%		C2	330pF ± 10%
	R	0Ω		R	0Ω

Table 1 Constants Guaranteed for Ceramic Resonator Oscillation

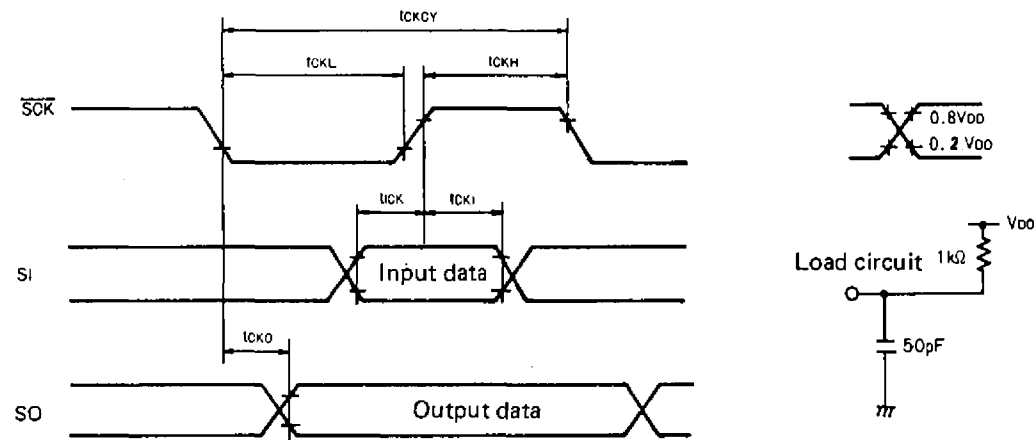


Fig. 6 Serial Input/Output Timing

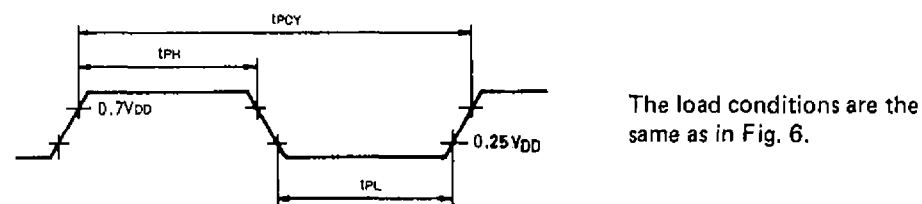


Fig. 7 Pulse Output Timing at Port PE0

LC6520C,6520H,6522C,6522H

Circuit Configuration	Frequency	Predivider Option (Cycle Time)	V _{DD}	Remarks
Ceramic Resonator Option	400 kHz	1/1 (10 μ s)	3 to 5.5V	Unusable with 1/3, 1/4 predivider
	800 kHz	1/1 (5 μ s) 1/3 (15 μ s) 1/4 (20 μ s)	4 to 5.5V 4 to 5.5V 4 to 5.5V	
	3 MHz	1/3 (4 μ s) 1/4 (5.33 μ s)	4 to 5.5V 4 to 5.5V	Unusable with 1/1 predivider
	4 MHz	1/3 (3 μ s) 1/4 (4 μ s)	4 to 5.5V 4 to 5.5V	Unusable with 1/1 predivider
External Clock Option or External Clock Drive by RC OSC Option	200 to 667 kHz 600 to 2000 kHz 800 to 2667 kHz 200 to 1444 kHz 600 to 4330 kHz 800 to 4330 kHz	1/1 (20 to 6 μ s) 1/3 (20 to 6 μ s) 1/4 (20 to 6 μ s) 1/1 (20 to 2.77 μ s) 1/3 (20 to 2.77 μ s) 1/4 (20 to 3.70 μ s)	3 to 5.5V 3 to 5.5V 3 to 5.5V 4 to 5.5V 4 to 5.5V 4 to 5.5V	
External Clock Drive by ceramic resonator OSC Option	The external clock drive is impossible. When using the external clock drive, specify the external clock option or RC OSC option.			
RC OSC Option	Used with 1/1 predivider, recommended constants (V _{DD} = 4 to 5.5V, V _{DD} = 3 to 5.5V). If used with other than recommended constants, the predivider option, frequency, V _{DD} range must be the same as for the external clock option.			

Table 2 Table of Oscillation, Predivider Option (All selectable combinations are shown. Do not use any other combinations than shown above.)

RC Oscillation Characteristic of the LC6520C, 6522C

Fig. 8 shows the RC oscillation characteristic of the LC6520C, 6522C. For the variation range of RC OSC frequency of the LC6520C, 6522C, the following are guaranteed at the external constants only shown below.

- 1) V_{DD} = 3.0V to 5.5V, T_a = -30°C to +70°C
 External constants C_{ext} = 270 pF, R_{ext} = 15 kohms
 222 kHz ≤ f_{mosc} ≤ 609 kHz
- 2) V_{DD} = 4.0V to 5.5V, T_a = -30°C to +70°C
 External constants C_{ext} = 220 pF, R_{ext} = 6.8 kohms
 515 kHz ≤ f_{mosc} ≤ 1156 kHz

If any other constants than specified above are used, the range of R_{ext} = 4 kohms to 23 kohms, C_{ext} = 150 pF to 400 pF must be observed. (See Fig. 8.)

Note 8: The oscillation frequency at V_{DD} = 5.0V, T_a = 25°C must be in the range of 350 kHz to 750 kHz.

Note 9: The oscillation frequency at V_{DD} = 4.0V to 5.5V, T_a = -30°C to +70°C and V_{DD} = 3.0V to 5.5V, T_a = -30°C to +70°C must be within the operation clock frequency range. (See Table 2.)

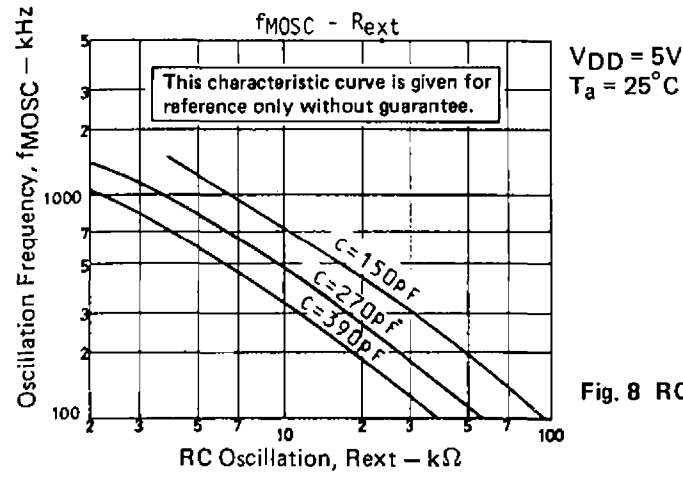


Fig. 8 RC Oscillation Frequency Data (Typ.)

Main Specifications of the LC6520H, 6522H

Absolute Maximum Ratings/ $T_a = 25^\circ C$, $V_{SS} = 0V$

				unit
Maximum Supply Voltage	V_{DD} max	V_{DD}	-0.3 to +7.0	V
Output Voltage	V_o	OSC2	Allowable up to voltage generated	V
Input Voltage	V_i (1)	OSC1 (Note 1)	-0.3 to $V_{DD}+0.3$	V
	V_i (2)	TEST, \overline{RES}	-0.3 to $V_{DD}+0.3$	V
	V_i (3)	PB0 to 3	-0.3 to +15	V
Input/Output Voltage	V_{IO} (1)	Port of OD type	-0.3 to +15	V
	V_{IO} (2)	Port of PU type	-0.3 to $V_{DD}+0.3$	V
Peak Output Current	I_{OP}	Input/output port	-2 to +20	mA
Average Output Current	I_{OA}	Input/output port: Per pin over the period of 100 msec.	-2 to +20	mA
	ΣI_{OA} (1)	Total current of PA0 to 3, PC0 to 3, PD0 to 3, and PE0 to 3 (Note 2)	-30 to +140	mA
	ΣI_{OA} (2)	Total current of PF0 to 3, PG0 to 3, and PI0 to 3, PJ0 to 3 (Note 2)	-30 to +140	mA
Allowable Power Dissipation	P_D max (1)	DIP package, $T_a = -30$ to $+70^\circ C$	600	mW
	P_D max (2)	QIP package, $T_a = -30$ to $+70^\circ C$	400	mW
Operating Frequency	T_{opg}		-30 to +70	$^\circ C$
Storage Temperature	T_{stg}		-55 to +125	$^\circ C$

Allowable Operating Conditions/ $T_a = -30$ to $+70^\circ C$, $V_{SS} = 0V$, $V_{DD} = 4.5$ to $5.5V$

			min	typ	max	unit
Operating Supply Voltage	V_{DD}	V_{DD}	4.5		5.5	V
Standby Supply Voltage	V_{st}	V_{DD} : RAM, resistor hold (Note 3)	1.8		5.5	V
"H"-Level Input Voltage	V_{IH} (1)	Port of OD type, PB0 to 3: Output Nch Tr OFF	$0.7V_{DD}$		+13.5	V
	V_{IH} (2)	Port of PU type: Output Nch Tr OFF	$0.7V_{DD}$		V_{DD}	V
	V_{IH} (3)	SCK, SI, INT: Output Nch Tr OFF	$0.8V_{DD}$		+13.5	V
	V_{IH} (4)	\overline{SCK} , SI, \overline{INT} : Output Nch Tr OFF	$0.8V_{DD}$		V_{DD}	V
	V_{IH} (5)	\overline{RES}	$0.8V_{DD}$		V_{DD}	V
	V_{IH} (6)	OSC1: External clock mode	$0.8V_{DD}$		V_{DD}	V
"L"-Level Input Voltage	V_{IL} (1)	Port: Output Nch Tr OFF	V_{SS}		$0.3V_{DD}$	V
	V_{IL} (2)	\overline{INT} , \overline{SCK} , SI: Output Nch Tr OFF	V_{SS}		$0.25V_{DD}$	V
	V_{IL} (3)	OSC1: External clock mode	V_{SS}		$0.25V_{DD}$	V
	V_{IL} (4)	TEST	V_{SS}		$0.3V_{DD}$	V
	V_{IL} (5)	\overline{RES}	V_{SS}		$0.25V_{DD}$	V
Operating Frequency (Cycle Time)	f_{op} (T_{cyc})		See Table 2. (0.92)		(20)	(μs)

External Clock Conditions (When the external clock option is selected)

Frequency	f_{ext}	OSC1: Fig. 1	See Table 2.	
Pulse Width	t_{extH} , t_{extL}	OSC1: Fig. 1	90	ns
Rise/Fall Time	t_{extR} , t_{extF}	OSC1: Fig. 1		30 ns

Oscillation Guaranteed Constants
Ceramic Resonator Oscillation

Fig. 2

See Table 1.

LC6520C,6520H,6522C,6522H

Electrical Characteristics/ $T_A = -30$ to $+70^{\circ}\text{C}$, $V_{SS} = 0\text{V}$, $V_{DD} = 4.5$ to 5.5V			min	typ	max	unit
"H"-Level Input Current	I_{IH} (1)	Port of open drain type, PB_0 to 3: Output Nch Tr OFF, Including Nch Tr OFF leakage current, $V_{IN} = 13.5\text{V}$			+5.0	μA
"L"-Level Input Current	I_{IH} (2)	OSC1: External clock mode, $V_{IN} = V_{DD}$			+1.0	μA
	I_{IL} (1)	Port of open drain type, PB_0 to 3: Output Nch Tr OFF, $V_{IN} = V_{SS}$	-1.0			μA
	I_{IL} (2)	Port with pull-up resistance: Output Nch Tr OFF, $V_{IN} = V_{SS}$	-1.3	-0.35		mA
	I_{IL} (3)	RES: $V_{IN} = V_{SS}$	-45	-10		μA
	I_{IL} (4)	OSC1: External clock mode, $V_{IN} = V_{SS}$	-1.0			μA
"H"-Level Output Voltage	V_{OH} (1)	Port with pull-up resistance: $I_{OH} = -50\mu\text{A}$	$V_{DD}-1.2$			V
	V_{OH} (2)	Port with pull-up resistance: $I_{OH} = -10\mu\text{A}$	$V_{DD}-0.5$			V
"L"-Level Output Voltage	V_{OL} (1)	Port: $I_{OL} = 10\text{mA}$			1.5	V
	V_{OL} (2)	Port: $I_{OL} = 1\text{mA}$, When I_{OL} of each port is 1 mA or less.			0.5	V
Hysteresis Voltage	V_{Hys}	RES, INT, SCK, SI, OSC1 of Schmitt type (Note 6)		$0.1V_{DD}$		V
Current Dissipation						
Ceramic Resonator Oscillation	I_{DDOP} (1)	V_{DD} : Fig. 2, 4MHz, Operating mode, Output Nch Tr OFF, Port = V_{DD}		5	10	mA
External Clock	I_{DDOP} (2)	V_{DD} : 200 kHz to 4330 kHz, Operating mode, Output Nch Tr OFF, Port = V_{DD}		5	10	mA
Standby Mode	I_{DDST}	V_{DD} : $V_{DD} = 5.5\text{V}$ (Output Nch Tr OFF, $V_{DD} = 3\text{V}$ Port = V_{DD})		0.05	10	μA
				0.025	5	μA
Oscillation Characteristics						
Ceramic Resonator Oscillation						
Oscillation Frequency	f_{CFOSC} (Note 4)	OSC1, OSC2: Fig. 2 $f_0 = 4\text{MHz}$	3920	4000	4080	kHz
Oscillation Stabilizing Period	t_{CFS}	Fig. 3 $f_0 = 4\text{MHz}$			10	ms
Pull-up Resistance						
I/O Port Pull-up Resistance	R_{pp}	Port of PU type: $V_{DD} = 5\text{V}$		14		k Ω
External Reset Characteristics						
"H"-Level Threshold	V_{tH}		$0.5V_{DD}$		$0.8V_{DD}$	V
"L"-Level Threshold	V_{tL}		$0.25V_{DD}$		$0.5V_{DD}$	V
Reset Time	T_{RST}		See Fig. 4.			
Pin Capacitance	CP	$f = 1\text{MHz}$, Other than pins to be tested, $V_{IN} = V_{SS}$		10		pF
Serial Clock						
Input Clock Cycle Time	t_{CKCY} (1)	SCK: Fig. 5	3.0			μs
Output Clock Cycle Time	t_{CKCY} (2)	SCK: ($T_{CYC} = 4 \times$ System clock period), Fig. 5		$64 \times T_{CYC}$		μs
Input Clock "L"-Level Pulse Width	t_{CKL} (1)	SCK: Fig. 5	1.0			μs
Output Clock "L"-Level Pulse Width	t_{CKL} (2)	SCK: Fig. 5		$32 \times T_{CYC}$		μs

Continued on next page.

Continued from preceding page.

			min	typ	max	unit
Input Clock "H"-Level Pulse Width	tCKH (1)	$\overline{\text{SCK}}$: Fig. 5	1.0			μs
Output Clock "H"-Level Pulse Width	tCKH (2)	$\overline{\text{SCK}}$: Fig. 5		32 x TCYC		μs
Serial Input Data Setup Time	tICK	SI: Specified for \uparrow of $\overline{\text{SCK}}$, Fig. 5	0.5			μs
Serial Input Data Hold Time	tCKI	SI: Specified for \uparrow of $\overline{\text{SCK}}$, Fig. 5	0.5			μs
Serial Output Output Delay Time	tCKO	SO: Specified for \downarrow of $\overline{\text{SCK}}$, Nch OD only: External 1 kohm, external 50 pF, Fig. 5			0.5	μs
Pulse Output Period	tpCY	PEO: TCYC = 4 x System clock period, Nch OD only: External 1 kohm, external 50 pF, Fig. 6		64 x TCYC		μs
"H"-Level Pulse Width	tpH	PEO:		32 x TCYC \pm 10%		μs
"L"-Level Pulse Width	tpL	PEO:		32 x TCYC \pm 10%		μs

Note 1: When oscillated internally under the oscillating conditions in Fig. 2, up to the oscillation amplitude generated is allowable.

Note 2: Average over the period of 100 msec.

Note 3: Operating supply voltage VDD must be held until the standby mode is entered after the execution of the HALT instruction. The PA3 (or PA0 to 3) pin must be free from chattering during the HALT instruction execution cycle.

Note 4: fCFOSC represents an oscillatable frequency. There is a tolerance of approximately 1% between the center frequency at the ceramic mode and the nominal value presented by the ceramic resonator supplier. For details, refer to the specification for the ceramic resonator.

Note 5: When mounting the QIP version on the board, do not dip it in solder.

Note 6: The OSC1 becomes the Schmitt type when the OSC option is the external clock OSC.

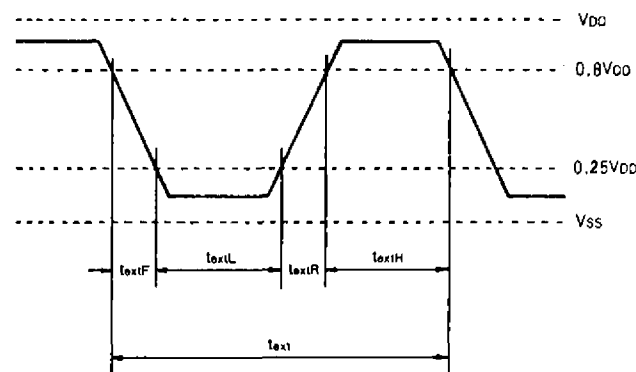
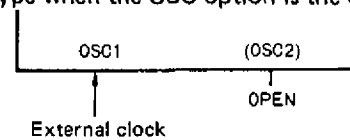


Fig. 1 External Clock Input Waveform

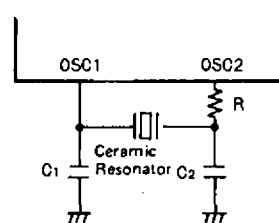


Fig. 2 Ceramic Resonator Oscillation Circuit

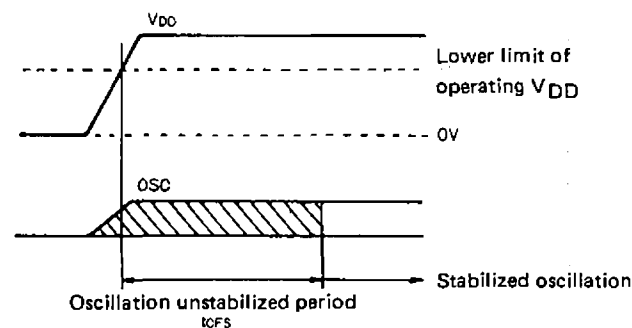


Fig. 3 Oscillation Stabilizing Period

4MHz (Murata) CSA4.00MG	C1	33pF ± 10%
	C2	33pF ± 10%
	R	0Ω
4MHz (Kyocera) KBR4.0MS	C1	33pF ± 10%
	C2	33pF ± 10%
	R	0Ω

Table 1 Constants Guaranteed for Ceramic Resonator Oscillation

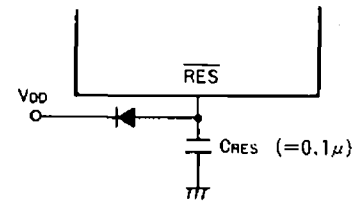


Fig. 4 Reset Circuit

Note 7: When the rise time of the power supply is 0, the reset time becomes 10 ms to 100 ms at $C_{RES} = 0.1 \mu F$. If the rise time of the power supply is long, the value of C_{RES} must be increased so that the reset time becomes 10 ms or greater.

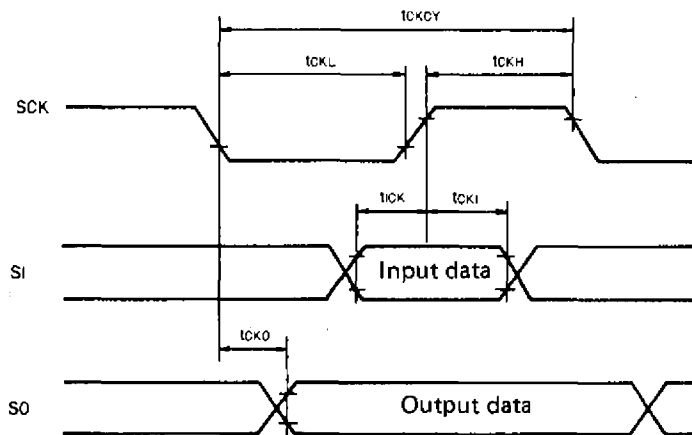


Fig. 5 Serial Input/Output Timing

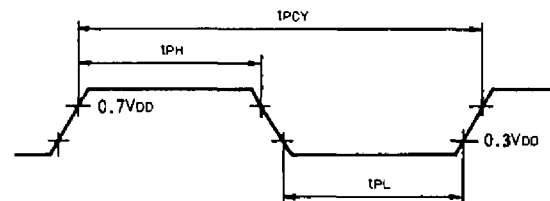
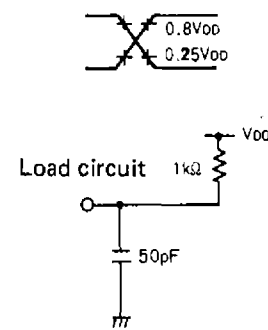


Fig. 6 Pulse Output Timing at Port PE0

The load conditions are the same as in Fig. 5.

Circuit Configuration	Frequency	Predivider Option (Cycle Time)	VDD	Remarks
Ceramic Resonator OSC Option	4 MHz	1/1 (1 μs)	4.5 to 5.5V	
External Clock Option	200 to 4330 kHz	1/1 (20 to 0.92 μs)	4.5 to 5.5V	
External Clock Drive by Ceramic Resonator OSC Option	The external clock drive is impossible. When using the external clock drive, specify the external clock option.			

Table 2 Table of Oscillation, Predivider Option (All selectable combinations are shown. Do not use any other combinations than shown above.)

Notes for Standby Function Application

The LC6520, LC6522 provide the standby function called HALT mode to minimize the current dissipation when the program is in the wait state.

The standby function is controlled by the HALT instruction, PA pin, $\overline{\text{RES}}$ pin, and serial transfer completion signal. A peripheral circuit and program must be so designed as to provide precise control of the standby function. In most applications where the standby function is performed, voltage regulation, instantaneous break of power, and external noise are not negligible. When designing an application circuit and program, whether or not to take some measures must be considered according to the extent to which these factors are allowed. This section mainly describes power failure backup for which the standby function is mostly used. A sample application circuit where the standby function is performed precisely is shown below and notes for circuit design and program design are also given below.

When using the standby function, the application circuit shown below must be used and the notes must be also fully observed.

If any other method than shown in this section is applied, it is necessary to fully check the environmental conditions such as power failure and the actual operation of an application equipment.

1. HALT mode release conditions

1-1. Supplementary description of release by serial transfer completion signal

On completion of serial transfer, the HALT mode is released and the execution of the program starts with an instruction immediately following the HALT instruction. This function can be used to execute the program only when serial transfer occurs, placing the program in the wait state when no serial transfer occurs. This function is effective in reducing the current dissipation or clock noise.

— Notes —

- Release by the serial transfer completion signal is available only when the RC mode is used for system clock generation; and unavailable when the ceramic mode is used.
- On completion of serial transfer, the HALT mode is released unconditionally. In an application, such as capacitor backup application, where the current dissipation must be kept as low as possible during backup and serial transfer by external clock is also used, the HALT mode is released when serial data is transferred externally during backup.

1-2. Summary of HALT release conditions

The HALT mode setting, release conditions are shown in Table 1.

Table 1 HALT mode setting, release conditions

HALT mode setting conditions	HALT mode release conditions
HALT instruction Provided that PA ₃ , (PA ₃ to PA ₀ or PA ₃ is program-selectable) is at high level.	1 Reset (Low level is applied to $\overline{\text{RES}}$.) 2 Low level is applied to PA ₃ , (PA ₃ to PA ₀ or PA ₃ is program-selectable.) 3 Serial transfer completion.

Note) HALT mode release conditions (2), (3) are available only when the RC mode is used for system clock generation; and unavailable when the ceramic mode is used.

2. Proper cares in using standby function

When using the standby function, an application circuit and program must be designed with the following in mind.

- (1) The supply voltage at the standby state must not be less than specified.
- (2) Input timing and conditions of each control signal ($\overline{\text{RES}}$, port A, serial transfer) must be observed at the standby initiate/release state.
- (3) Release operation must not be overlapped at the time of execution of the HALT instruction.

A sample application where the standby function is used for power failure backup is shown below as a concrete method to observe these notes. A sample application circuit, its operation, and notes for program design are given below.

Power failure backup is an application where power failure of the main power source is detected and the HALT instruction is executed to cause the standby state to be entered. The current dissipation is minimized and a backup capacitor is used to retain the contents of the internal registers for a certain period of time. After power is restored, a reset occurs automatically and the execution of the program starts at address 000H of the program counter (PC). Shown below are sample applications where the program selects or not between power-ON reset and reset after power is restored, notes, measures for instantaneous break of AC power, and notes for serial transfer.

2-1. Sample application 1 where the standby function is used for power failure backup

Shown below is a sample application where the program does not select between power-ON reset and reset after power is restored.

2-1-1. Sample application circuit – (1)

Fig. 2-1 shows a sample application where the standby function is used for power failure backup.

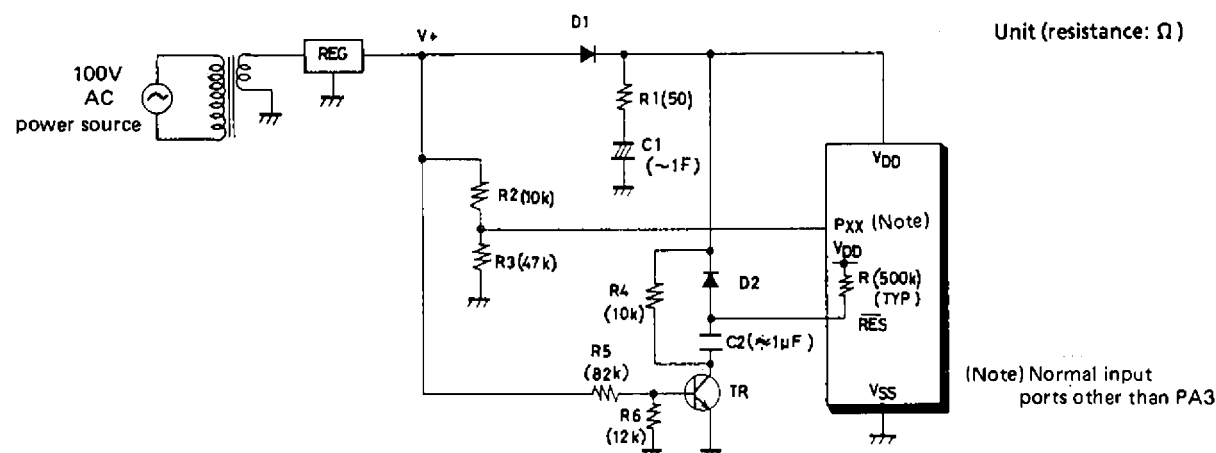


Fig. 2-1. Sample application – (1) where the standby function is used for power failure backup

2-1-2. Operating waveform in sample application circuit – (1)

The operating waveform in the sample application circuit in Fig. 2-1 is shown in Fig. 2-2. The mode is roughly divided as follows: a, Power-ON reset, b, Instantaneous break of main power, c, Return from power failure backup.

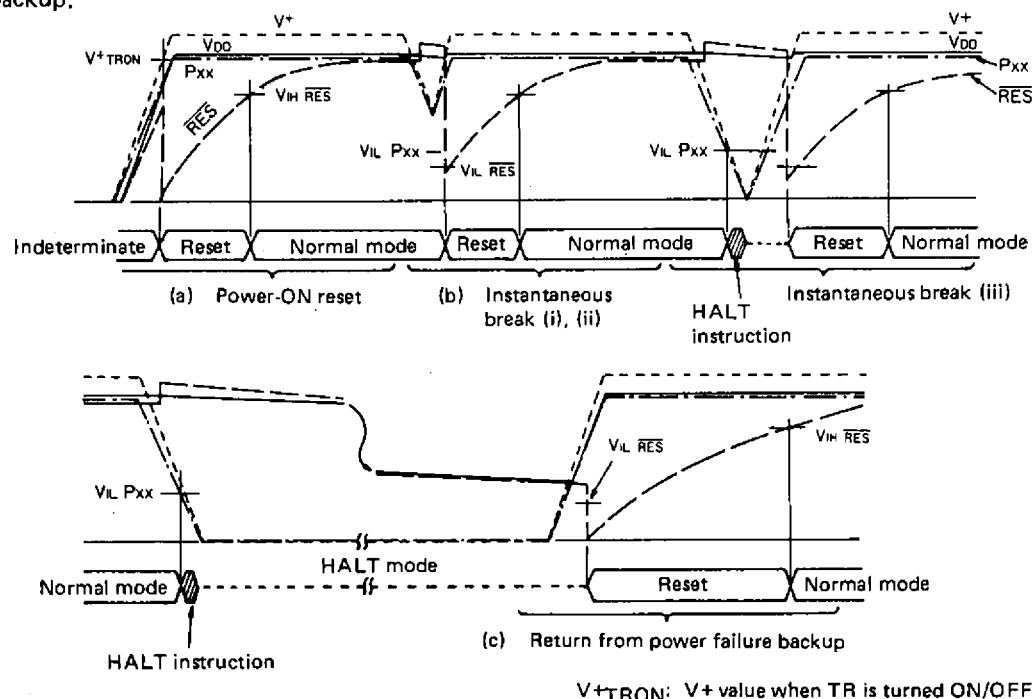


Fig. 2-2. Operating waveforms — (1) in sample application circuit

2-1-3. Operation of sample application circuit — (1)

(a) At the time of power-ON reset

After power rises, a reset occurs automatically and the execution of the program starts at address 000H of the program counter (PC).

— Note —

This sample application circuit provides an indeterminate region where no reset occurs before the operating V_{DD} range is entered.

(b) At the time of instantaneous break

(i) When the PXX input voltage does not meet V_{IL} (The PXX input level does not get lower than input threshold level V_{IL}) and the RES input voltage only meets V_{IL} :

A reset occurs in the normal mode, providing the same operation as power-ON reset.

(ii) When both of the PXX input voltage and RES input voltage do not meet V_{IL} :

The program continues running in the normal mode.

(iii) When both of the PXX input voltage and RES input voltage meet V_{IL} :

When two pollings do not regard the PXX input voltage as "L" level, the HALT mode is not entered and a reset occurs.

When two pollings regard the PXX input voltage as "L" level, the HALT mode is entered and after power is restored a reset occurs, releasing the standby mode.

(c) At the time of return from power failure backup

After power is restored, a reset occurs, releasing the standby mode.

2-1-4. Notes for design of sample application circuit — (1)

• V+rise time and C₂

Make the time constant (C₂, R) of the reset circuit 10 times as long as the V+rise time. (R: ON-chip resistor, 500 kohm typ.)

Make the V+rise time shorter (up to 20 ms).

• R₁ and C₁

Make the R₁ value as small as possible. Make the C₁ value as large as possible according to the backup time calculated, (Fix the R₁ value so that the C₁ charging current does not exceed the power source capacity.)

• R₂ and R₃

Make the "H"-level input voltage applied to the PXX pin equal to V_{DD} .

• R₄

Fix the time constant of C₂ and C₄ so that C₂ can discharge during the period of time from when V+ gets lower than V_{+TROM} (TR OFF) at the time of instantaneous break until the PXX input voltage gets lower than V_{IL} (because release by reset is not available after the HALT mode is entered by instantaneous break).

• R₅ and R₆

Make V+ ($V_{BE} \approx 0.6V$ is obtained by R₅ and R₆) when the reset circuit works (Tr ON) more than (operating $V_{DD\ min} + V_F$ of diode D₁). Observing this note, make V+ as low as possible to provide a reset early enough after power-ON.

• Backup time

The normal operation continues with a relatively high current dissipation from when power failure is detected by the PXX until the HALT instruction is executed. Fix the C₁ value so that the standby supply voltage is held during backup time of set + above-mentioned time.

2-1-5. Notes for software design

• Design the program so that port A₀ to A₂ cannot be used for standby release and port A₃ is brought to "H" level at the standby mode.

• Input a standby request to a normal input port other than the PA₃ and check by polling this input port twice.

(Example)

```

:
BP1      AAA      ; 1st polling
RCTL     3        ; Interrupt inhibit
BP1      AAA      ; 2nd polling
HALT
AAA:     :

```

2.2. Sample application 2 where the standby function is used for power failure backup

Shown below is a sample application where the program selects between power-ON reset and reset after power is restored.

2.2-1. Sample application circuit – (2) (No instantaneous break in power source)

Fig. 2-3 shows a sample application where the standby function is used for power failure backup.

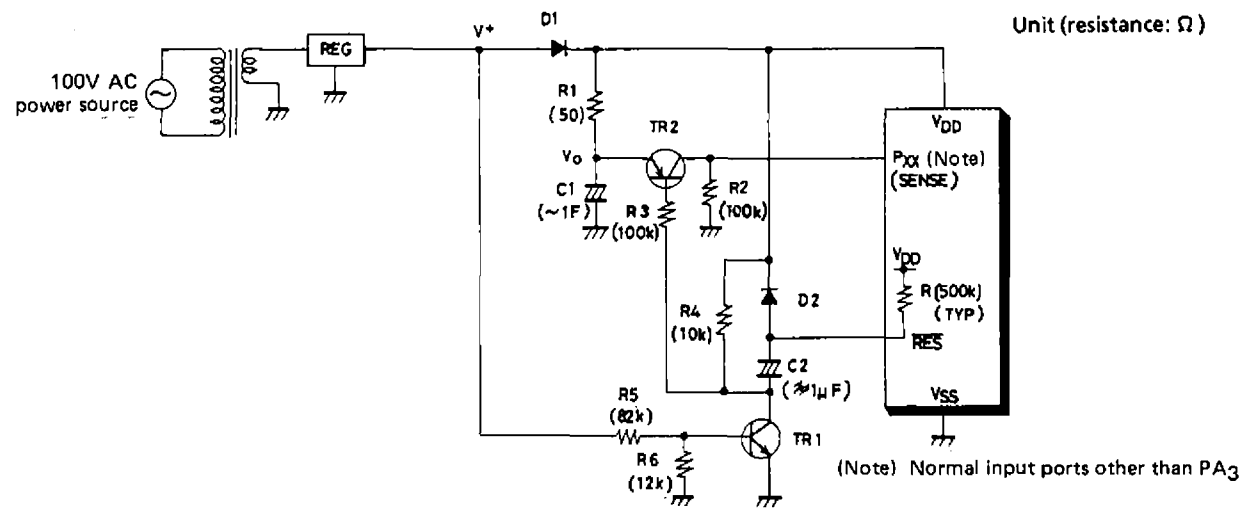


Fig. 2-3 Sample application – (2) where the standby function is used for power failure backup

2.2-2. Operating waveform in sample application circuit – (2)

The operating waveform in the sample application circuit in Fig. 2-3 is shown in Fig. 2-4. The mode is roughly divided as follows: a, Power-ON reset, b. Return from power failure backup.

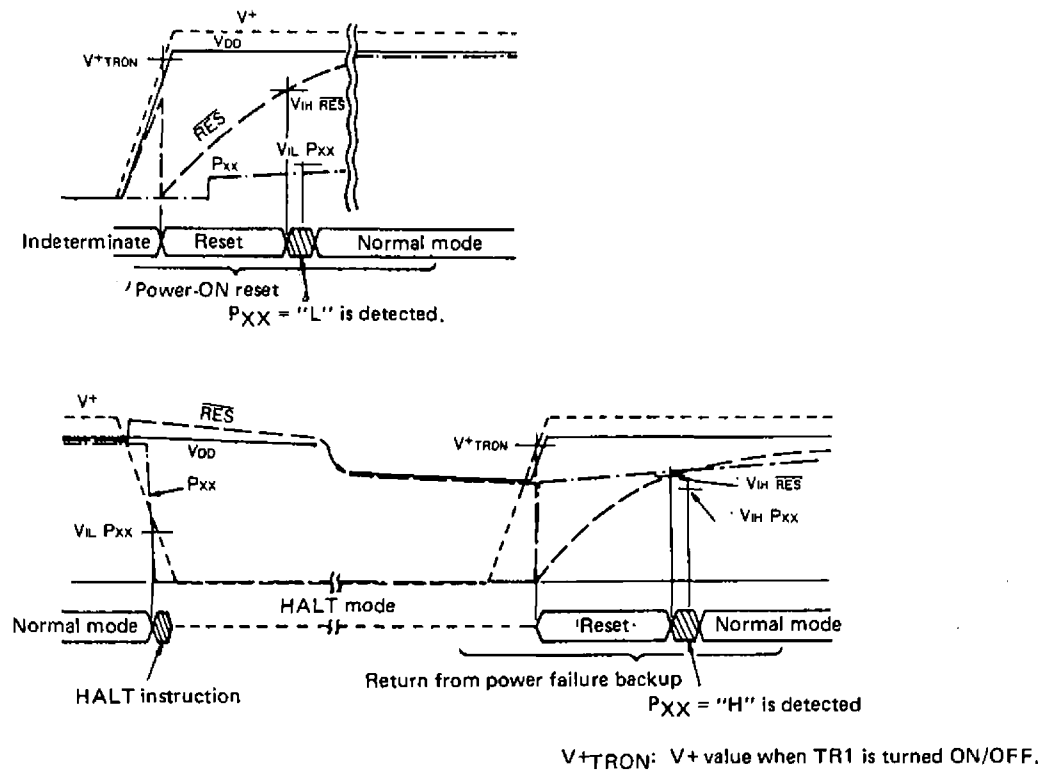


Fig. 2-4. Operating waveform – (2) in sample application circuit

2-2-3. Operation of sample application circuit – (2)

- At the time of power-ON reset
The operation and notes are the same as for sample application circuit – (1), except that after reset release $P_{XX} = "L"$ is program-detected to decide program start after initial reset.
- Standby initiation
When one polling regards the P_{XX} input voltage as "L" level, the HALT mode is entered.
- At the time of return from power failure backup
After power is restored, a reset occurs, releasing the standby mode. After standby release $P_{XX} = "H"$ is program-detected, deciding program start after power is restored.

– Note –

If power is restored after V_{DD} during power failure backup gets lower than V_{IH} on the P_{XX} , $P_{XX} = "L"$ may be program-detected, deciding program start after initial reset.

2-2-4. Notes for design of sample application circuit – (2)

- R_2 and R_3
Fix the R_2 value so that $R_2 \gg R_1$ is yielded and fix the R_3 value so that I_B of TR2 is limited.
- R_4
There is no severe restriction on the R_4 value, but fix it so that C_2 can discharge quickly.
Other notes are the same as for sample application circuit – (1).

2-2-5. Notes for software design

- Design the program so that port A_0 to A_2 cannot be used for standby release and port A_3 is brought to "H" level.
- Input a standby request to a normal input port other than the PA_3 and check by polling this input port once.

(Example)

```

:
BP1      AAA      ; Polling
HALT     ; Standby
AAA:
:
    
```

2-3. Sample application 3 where the standby function is used for power failure backup

2-3-1. Sample application circuit – (3) (There is an instantaneous break in power source.)

Fig. 2-5. shows a sample application where the standby function is used for power failure backup.

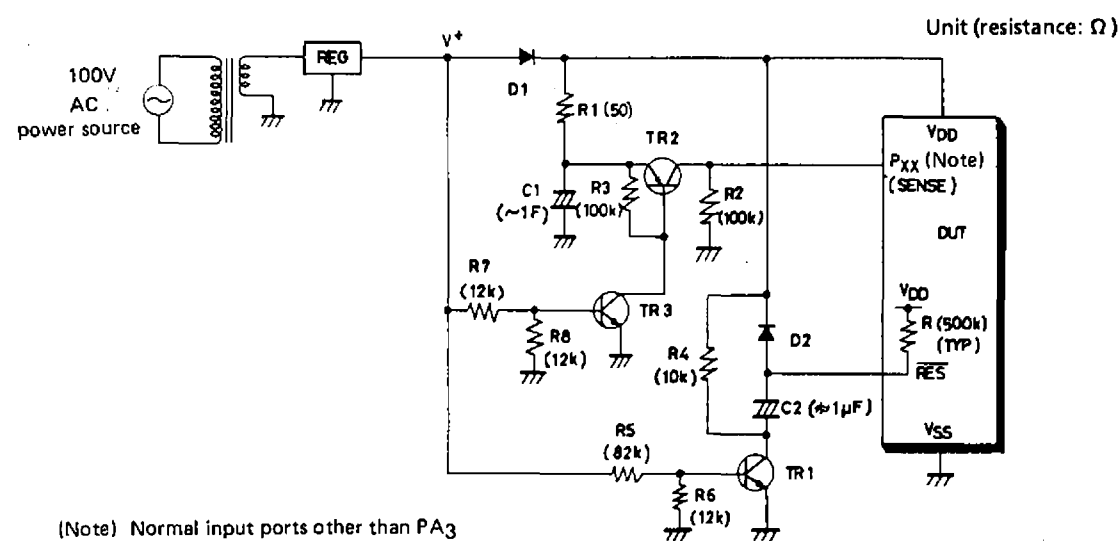


Fig. 2-5 Sample application – (3) where the standby function is used for power failure backup

2-3-2. Operating waveform in sample application circuit – (3)

The operating waveform in the sample application circuit in fig. 2-5 is shown in Fig. 2-6. The mode is roughly divided as follows: a, Power-ON reset, b, Instantaneous break of main power, c, Return from power failure backup.

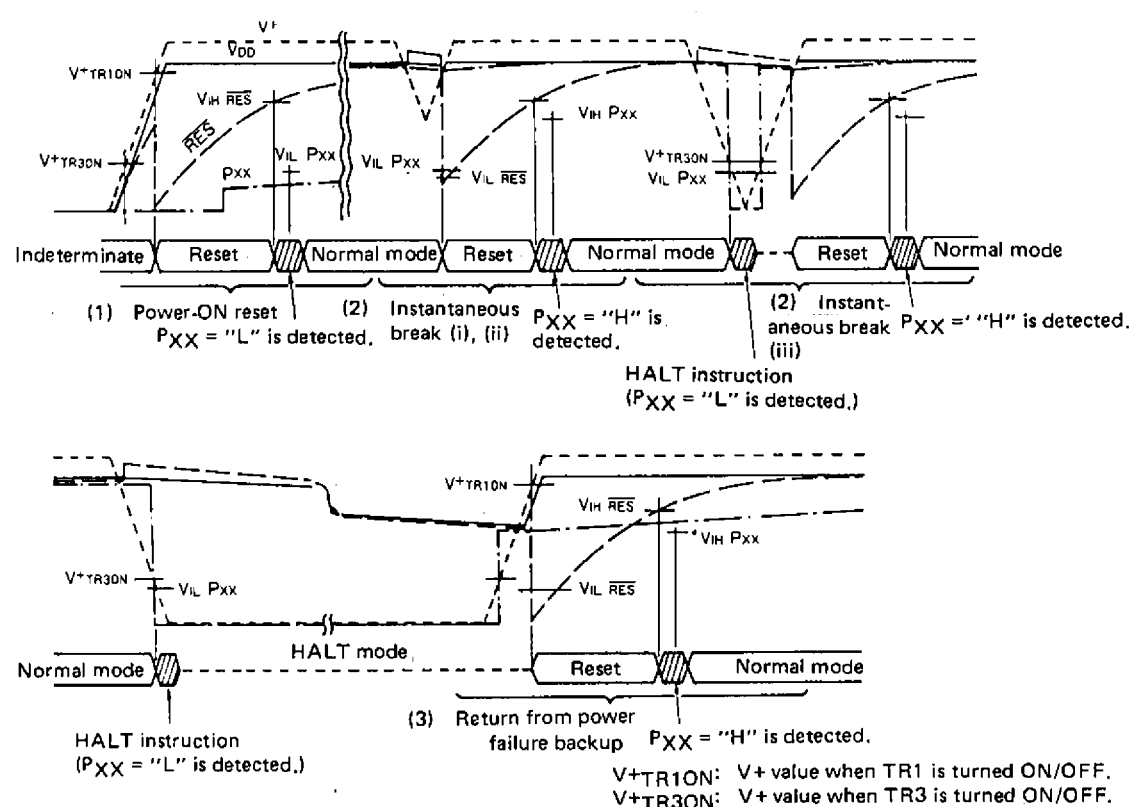


Fig. 2-6. Operating waveform in sample application circuit – (3)

2-3-3. Operation of sample application circuit – (3)

- (a) At the time of power-ON reset
The operation and notes are the same as for sample application circuit – (2)
- (b) At the time of instantaneous break
 - (i) When the PXX input voltage does not meet V_{IL} (the PXX input level does not get lower than input threshold level V_{IL}) and the \overline{RES} input voltage only meets V_{IL} :
A reset occurs in the normal mode. After reset release PXX = "H" is program-detected, deciding program start after instantaneous break.
 - (ii) When both of the PXX input voltage and \overline{RES} input voltage do not meet V_{IL} :
The program continues running in the normal mode.
 - (iii) When both of the PXX input voltage and \overline{RES} input voltage meet V_{IL} :
When two pollings do not regard the PXX input voltage as "L" level, the HALT mode is not entered and a reset occurs.
When two pollings regard the PXX input voltage as "L" level, the HALT mode is entered and after power is restored, a reset occurs, releasing the standby mode. After standby release PXX = "H" is program-detected, deciding program start after instantaneous break.
- (c) At the time of return from power failure backup
The operation and notes are the same as for sample application circuit – (2)

2-3-4. Notes for design of sample application circuit – (3)

- R3
Bias resistance of TR2
 - R7 and R8
Fix the R7 and R8 values so that TR3 is turned ON/OFF at approximately 1.5V of V+.
- Other notes are the same as for sample application circuit – (1)

2-3-5. Notes for software design

Same as for sample application circuit – (1)

2-4. Notes (1) for providing serial transfer

Notes for providing power failure backup and serial transfer

This application assigns top priority to power failure backup. When power failure backup is provided, serial transfer may not be provided normally.

- (1) When the internal clock is used for the serial clock:
Execute the serial transfer start instruction immediately before executing the HALT instruction. If this is done during serial transfer, the power failure backup mode is entered without normal transfer.
- (2) When the external clock is used for the serial clock:
When power failure is detected, it is most prioritized that the HALT mode is entered, providing power failure backup. It is necessary to design an application system where no release signal by serial transfer completion is inputted to the HALT instruction executing cycle and no release signal is inputted during backup.

2-5. Notes (2) for providing serial transfer

Notes for providing HALT and serial transfer for program standby without power failure backup

This application assigns top priority to serial transfer. The following notes for system design must be observed.

- (1) When the internal clock is used for the serial clock:
Transfer starts when it is ready on both sides. When transfer is not ready on the other side, the HALT instruction is executed to reduce the current dissipation. When transfer is ready, the HALT release signal (RES, PA) causes return from the standby mode, starting serial transfer.
- (2) When the external clock is used for the serial clock:
Synchronization must be provided between microcomputers to prevent the HALT instruction and HALT release signal (RSIOEND) from overlapping. When transfer is ready, the serial transfer start instruction is executed and the program is placed in the wait state. The other side adjusts thime so that no overlap occurs between the HALT instruction and transfer completion and starts serial transfer. On completion of transfer, the HALT mode is released and the program is executed with an instruction immediately following the HALT instruction.

LC6520, LC6522 INSTRUCTION SET

Symbol Description

AC	: Accumulator	M(DP)	: Memory addressed by DP	(), ()	: Contents
ACt	: Accumulator bit t	P(DP _L)	: Input/output port addressed by DP _L	←	: Transfer and direction
CF	: Carry flag	PC	: Program counter	+	: Addition
CTL	: Control register	STACK	: Stack register	-	: Subtraction
DP	: Data pointer	TM	: Timer	∧	: AND
E	: E register	TMF	: Timer (internal) interrupt request flag	∨	: OR
EXTF	: External interrupt request flag	At, Ma, La	: Working register	⊕	: Exclusive OR
Fn	: Flag bit n	ZF	: Zero flag		
M	: Memory				

Instruction group		Mnemonic	Instruction code		Bytes	Cycles	Function	Description	Status flag affected	Remarks												
			D ₇ D ₆ D ₅ D ₄	D ₃ D ₂ D ₁ D ₀																		
Accumulator manipulation instructions	CLA	Clear AC	1 1 0 0	0 0 0 0	1	1	AC ← 0	The AC contents are cleared.	ZF	* 1												
	CLC	Clear CF	1 1 1 0	0 0 0 1	1	1	CF ← 0	The CF contents are cleared.	CF													
	STC	Set CF	1 1 1 1	0 0 0 1	1	1	CF ← 1	The CF is set.	CF													
	CMA	Complement AC	1 1 1 0	1 0 1 1	1	1	AC ← \overline{AC}	The AC contents are complemented.	ZF													
	INC	Increment AC	0 0 0 0	1 1 1 0	1	1	AC ← (AC) + 1	The AC contents are incremented +1.	ZF CF													
	DEC	Decrement AC	0 0 0 0	1 1 1 1	1	1	AC ← (AC) - 1	The AC contents are decremented -1.	ZF CF													
	RAL	Rotate AC left through CF	0 0 0 0	0 0 0 1	1	1	AC ₀ ← (CF), AC _{n+1} ← (AC _n), CF ← (AC ₀)	The AC contents are shifted left through the CF.	ZF CF													
	TAE	Transfer AC to E	0 0 0 0	0 0 1 1	1	1	E ← (AC)	The AC contents are transferred to the E.														
Memory manipulation instructions	XAE	Exchange AC with E	0 0 0 0	1 1 0 1	1	1	(AC) ↔ (E)	The AC contents and the E contents are exchanged.														
	INM	Increment M	0 0 1 0	1 1 1 0	1	1	M(DP) ← (M(DP)) + 1	The M(DP) contents are incremented +1.	ZF CF													
	DEM	Decrement M	0 0 1 0	1 1 1 1	1	1	M(DP) ← (M(DP)) - 1	The M(DP) contents are decremented -1.	ZF CF													
	SMB bit	Set M data bit	0 0 0 0	1 0 B ₁ B ₀	1	1	M(DP, B ₁ B ₀) ← 1	A single bit of the M(DP) specified with B ₁ B ₀ is set.														
Arithmetic operation/comparison instructions	RMB bit	Reset M data bit	0 0 1 0	1 0 B ₁ B ₀	1	1	M(DP, B ₁ B ₀) ← 0	A single bit of the M(DP) specified with B ₁ B ₀ is reset.	ZF													
	AD	Add M to AC	0 1 1 0	0 0 0 0	1	1	AC ← (AC) + (M(DP))	Binary addition of the AC contents and the M(DP) contents is performed and the result is stored in the AC.	ZF CF													
	ADC	Add M to AC with CF	0 0 1 0	0 0 0 0	1	1	AC ← (AC) + (M(DP)) + (CF)	Binary addition of the AC, CF contents and the M(DP) contents is performed and the result is stored in the AC.	ZF CF													
	DAA	Decimal adjust AC in addition	1 1 1 0	0 1 1 0	1	1	AC ← (AC) + 6	6 is added to the AC contents.	ZF													
	DAS	Decimal adjust AC in subtraction	1 1 1 0	1 0 1 0	1	1	AC ← (AC) + 10	10 is added to the AC contents.	ZF													
	EXL	Exclusive or M to AC	1 1 1 1	0 1 0 1	1	1	AC ← (AC) ∨ (M(DP))	The AC contents and the M(DP) contents are exclusive-ORed and the result is stored in the AC.	ZF													
	AND	And M to AC	1 1 1 0	0 1 1 1	1	1	AC ← (AC) ∧ (M(DP))	The AC contents and the M(DP) contents are ANDed and the result is stored in the AC.	ZF													
	OR	Or M to AC	1 1 1 0	0 1 0 1	1	1	AC ← (AC) ∨ (M(DP))	The AC contents and the M(DP) contents are ORed and the result is stored in the AC.	ZF													
	CM	Compare AC with M	1 1 1 1	1 0 1 1	1	1	(M(DP)) + (AC) + 1	The AC contents and the M(DP) contents are compared and the CF and ZF are set/reset. <table><tr><th>Comparison result</th><th>CF</th><th>ZF</th></tr><tr><td>(M(DP)) > (AC)</td><td>0</td><td>0</td></tr><tr><td>(M(DP)) = (AC)</td><td>1</td><td>1</td></tr><tr><td>(M(DP)) < (AC)</td><td>1</td><td>0</td></tr></table>	Comparison result	CF	ZF	(M(DP)) > (AC)	0	0	(M(DP)) = (AC)	1	1	(M(DP)) < (AC)	1	0	ZF CF	
Comparison result	CF	ZF																				
(M(DP)) > (AC)	0	0																				
(M(DP)) = (AC)	1	1																				
(M(DP)) < (AC)	1	0																				
Load/store instructions	CI data	Compare AC with immediate data	0 0 1 0 0 1 0 0	1 1 0 0 1 ₃ 1 ₂ 1 ₁ 1 ₀	2	2	($I_3 I_2 I_1 I_0$) + (AC) + 1	The AC contents and the immediate data $I_3 I_2 I_1 I_0$ are compared and the ZF and CF are set/reset. <table><tr><th>Comparison result</th><th>CF</th><th>ZF</th></tr><tr><td>$I_3 I_2 I_1 I_0 > (AC)$</td><td>0</td><td>0</td></tr><tr><td>$I_3 I_2 I_1 I_0 = (AC)$</td><td>1</td><td>1</td></tr><tr><td>$I_3 I_2 I_1 I_0 < (AC)$</td><td>1</td><td>0</td></tr></table>	Comparison result	CF	ZF	$I_3 I_2 I_1 I_0 > (AC)$	0	0	$I_3 I_2 I_1 I_0 = (AC)$	1	1	$I_3 I_2 I_1 I_0 < (AC)$	1	0	ZF CF	
	Comparison result	CF	ZF																			
	$I_3 I_2 I_1 I_0 > (AC)$	0	0																			
	$I_3 I_2 I_1 I_0 = (AC)$	1	1																			
	$I_3 I_2 I_1 I_0 < (AC)$	1	0																			
	CLI data	Compare DPL with immediate data	0 0 1 0 0 1 0 1	1 1 0 0 1 ₃ 1 ₂ 1 ₁ 1 ₀	2	2	(DP _L) ∨ ($I_3 I_2 I_1 I_0$)	The DPL contents and the immediate data $I_3 I_2 I_1 I_0$ are compared.	ZF													
	LI data	Load AC with immediate data	1 1 0 0	1 ₃ 1 ₂ 1 ₁ 1 ₀	1	1	AC ← $I_3 I_2 I_1 I_0$	The immediate data $I_3 I_2 I_1 I_0$ is loaded in the AC.	ZF	* 1												
S	Store AC to M	0 0 0 0	0 0 1 0	1	1	M(DP) ← (AC)	The AC contents are stored in the M(DP).															
L	Load AC from M	0 0 1 0	0 0 0 1	1	1	AC ← (M(DP))	The M(DP) contents are loaded in the AC.	ZF														
XM data	Exchange AC with M, then modify DP _H with immediate data	1 0 1 0	0 M ₂ M ₁ M ₀	1	2	(AC) ↔ (M(DP)) DP _H ← (DP _H) ∨ (0 M ₂ M ₁ M ₀)	The AC contents and the M(DP) contents are exchanged and then the DP _H contents are modified with the contents of (DP _H) ∨ (0 M ₂ M ₁ M ₀).	ZF	The ZF is set/reset according to the result of (DP _H) ∨ (0 M ₂ M ₁ M ₀).													
X	Exchange AC with M	1 0 1 0	0 0 0 0	1	2	(AC) ↔ (M(DP))	The AC contents and the M(DP) contents are exchanged.	ZF	The ZF is set/reset according to the DP _H contents at the time of instruction execution.													
XI	Exchange AC with M, then increment DPL	1 1 1 1	1 1 1 0	1	2	(AC) ↔ (M(DP)) DPL ← (DPL) + 1	The AC contents and the M(DP) contents are exchanged and then the DPL contents are incremented +1.	ZF	The ZF is set/reset according to the result of (DPL + 1).													
XO	Exchange AC with M, then decrement DPL	1 1 1 1	1 1 1 1	1	2	(AC) ↔ (M(DP)) DPL ← (DPL) - 1	The AC contents and the M(DP) contents are exchanged and then the DPL contents are decremented -1.	ZF	The ZF is set/reset according to the result of (DPL - 1).													
RTBL	Read table data from program ROM	0 1 1 0	0 0 1 1	1	2	AC, E ← ROM (PCh, E, AC)	The contents of ROM addressed by the PC whose low-order 8 bits are replaced with the E and AC contents are loaded in the AC and E.															

LC6520C, 6520H, 6522C, 6522H

Instruction group	Mnemonic	Instruction code		Bytes	Cycles	Function	Description	Status flag affected	Remarks
		D ₇ D ₆ D ₅ D ₄	D ₃ D ₂ D ₁ D ₀						
Data pointer manipulation instructions	LDZ data	Load DPH with Zero and DPL with immediate data respectively	1 0 0 0	1 3 1 2 1 1 1 0	1 1	DPH ← 0 DPL ← 1 3 1 2 1 1 1 0	The DPH and DPL are loaded with 0 and the immediate data 1 3 1 2 1 1 1 0 respectively.		
	LHI data	Load DPH with immediate data	0 1 0 0	1 3 1 2 1 1 1 0	1 1	DPH ← 1 3 1 2 1 1 1 0	The DPH is loaded with the immediate data 1 3 1 2 1 1 1 0.		
	IND	Increment DPL	1 1 1 0	1 1 1 0	1 1	DPL ← (DPL) + 1	The DPL contents are incremented +1.	ZF	
	DED	Decrement DPL	1 1 1 0	1 1 1 1	1 1	DPL ← (DPL) - 1	The DPL contents are decremented -1.	ZF	
	TAL	Transfer AC to DPL	1 1 1 1	0 1 1 1	1 1	DPL ← (AC)	The AC contents are transferred to the DPL.		
	TLA	Transfer DPL to AC	1 1 1 0	1 0 0 1	1 1	AC ← (DPL)	The DPL contents are transferred to the AC.	ZF	
	XAH	Exchange AC with DPH	0 0 1 0	0 0 1 1	1 1	(AC) ↔ (DPH)	The AC contents and the DPH contents are exchanged.		
Working register manipulation instructions	XAt	Exchange AC with working register At	1 1 1 0	1 1 0 0	1 1	(AC) ↔ (A0)	The AC contents and the contents of working register At are exchanged. At is assigned one of A0, A1, A2, A3 according to t ₁ t ₀ .		
	XAO		1 1 1 0	0 1 0 0	1 1	(AC) ↔ (A1)			
	XA1		1 1 1 0	1 0 0 0	1 1	(AC) ↔ (A2)			
	XA2		1 1 1 0	1 1 0 0	1 1	(AC) ↔ (A3)			
	XHa	Exchange DPH with working register Ha	1 1 1 1	1 1 0 0	1 1	(DPH) ↔ (H0)	The DPH contents and the contents of working register Ha are exchanged. Ha is assigned either of H0 or H1 according to a.		
	XH1		1 1 1 1	1 1 0 1	1 1	(DPH) ↔ (H1)			
Flag manipulation instructions	XLa	Exchange DPL with working register La	1 1 1 1	0 1 0 0	1 1	(DPL) ↔ (L0)	The DPL contents and the contents of working register La are exchanged. La is assigned either of L0 or L1 according to a.		
	XL1		1 1 1 1	0 1 0 1	1 1	(DPL) ↔ (L1)			
Flag manipulation instructions	SFB flag	Set flag bit	0 1 0 1	B ₃ B ₂ B ₁ B ₀	1 1	F _n ← 1	The flag specified with B ₃ B ₂ B ₁ B ₀ is set.		
	RFB flag	Reset flag bit	0 0 0 1	B ₃ B ₂ B ₁ B ₀	1 1	F _n ← 0	The flag specified with B ₃ B ₂ B ₁ B ₀ is reset.	ZF	The flags are divided into 4 groups of F ₀ to F ₃ , F ₄ to F ₇ , F ₈ to F ₁₁ , F ₁₂ to F ₁₅ . The ZF is set/reset according to the 4 bits including a single bit specified with the immediate data B ₃ B ₂ B ₁ B ₀ .
Jump/subroutine instructions	JMP addr	Jump in the current bank	0 1 1 0	P ₇ P ₆ P ₅ P ₄	2 2	PC ← PC ₁₁ (or PC ₁₁) P ₁₀ P ₉ P ₈ P ₇ P ₆ P ₅ P ₄ P ₃ P ₂ P ₁ P ₀	A jump to the address specified with the PC ₁₁ (or PC ₁₁) and immediate data P ₁₀ P ₉ P ₈ P ₇ P ₆ P ₅ P ₄ P ₃ P ₂ P ₁ P ₀ occurs.		If the BANK and JMP instructions are executed consecutively, PC ₁₁ → PC ₁₁ .
	JPEA	Jump in the current page modified by E and AC	1 1 1 1	1 0 1 0	1 1	PC ₇ ~ 0 ← (E, AC)	A jump to the address specified with the contents of the PC whose low-order 8 bits are replaced by the E and AC contents occurs.		
	CZP addr	Call subroutine in the zero page	1 0 1 1	P ₃ P ₂ P ₁ P ₀	1 1	STACK ← (PC) + 1 PC ₁₁ ~ 6, PC ₁ ~ 0 ← 0 PC ₅ ~ 2 ← P ₃ P ₂ P ₁ P ₀	A subroutine in page 0 of bank 0 is called.		
	CAL addr	Call subroutine in the zero bank	1 0 1 0	P ₇ P ₆ P ₅ P ₄	2 2	STACK ← (PC) + 2 PC ₁₁ ~ 0 ← 0P ₁₀ P ₉ P ₈ P ₇ P ₆ P ₅ P ₄ P ₃ P ₂ P ₁ P ₀	A subroutine in bank 0 is called.		
	RT	Return from subroutine	0 1 1 0	0 0 1 0	1 1	PC ← (STACK)	A return from a subroutine occurs.		
	RTI	Return from interrupt routine	0 0 1 0	0 0 1 0	1 1	PC ← (STACK) CF ZF ← CSF, ZSF	A return from an interrupt service routine occurs.	ZF CF	
	BANK	Change bank	1 1 1 1	1 1 0 1	1 1	PC ₁₁ ← (PC ₁₁)	The bank is changed.		Effective only when used immediately before the JMP instruction.
Branch instructions	BAI addr	Branch on AC bit	0 1 1 1	P ₇ P ₆ P ₅ P ₄	2 2	PC ₇ ~ 0 ← P ₇ P ₆ P ₅ P ₄ P ₃ P ₂ P ₁ P ₀ if (AC _t) = 1	If a single bit of the AC specified with the immediate data t ₁ t ₀ is 1, a branch to the address specified with the immediate data P ₇ P ₆ P ₅ P ₄ P ₃ P ₂ P ₁ P ₀ within the same page occurs.		Mnemonic is BAI0 to BAI3 according to the value of t.
	BNAI addr	Branch on no AC bit	0 0 1 1	P ₇ P ₆ P ₅ P ₄	2 2	PC ₇ ~ 0 ← P ₇ P ₆ P ₅ P ₄ P ₃ P ₂ P ₁ P ₀ if (AC _t) = 0	If a single bit of the AC specified with the immediate data t ₁ t ₀ is 0, a branch to the address specified with the immediate data P ₇ P ₆ P ₅ P ₄ P ₃ P ₂ P ₁ P ₀ within the same page occurs.		Mnemonic is BNA0 to BNA3 according to the value of t.
	BMI addr	Branch on M bit	0 1 1 1	P ₇ P ₆ P ₅ P ₄	2 2	PC ₇ ~ 0 ← P ₇ P ₆ P ₅ P ₄ P ₃ P ₂ P ₁ P ₀ if (M(DP, t ₁ t ₀)) = 1	If a single bit of the M(DP) specified with the immediate data t ₁ t ₀ is 1, a branch to the address specified with the immediate data P ₇ P ₆ P ₅ P ₄ P ₃ P ₂ P ₁ P ₀ within the same page occurs.		Mnemonic is BM0 to BM3 according to the value of t.
	BNMI addr	Branch on no M bit	0 0 1 1	P ₇ P ₆ P ₅ P ₄	2 2	PC ₇ ~ 0 ← P ₇ P ₆ P ₅ P ₄ P ₃ P ₂ P ₁ P ₀ if (M(DP, t ₁ t ₀)) = 0	If a single bit of the M(DP) specified with the immediate data t ₁ t ₀ is 0, a branch to the address specified with the immediate data P ₇ P ₆ P ₅ P ₄ P ₃ P ₂ P ₁ P ₀ within the same page occurs.		Mnemonic is BNMI0 to BNMI3 according to the value of t.
	BPI addr	Branch on Port bit	0 1 1 1	P ₇ P ₆ P ₅ P ₄	2 2	PC ₇ ~ 0 ← P ₇ P ₆ P ₅ P ₄ P ₃ P ₂ P ₁ P ₀ if (P(DPL, t ₁ t ₀)) = 1	If a single bit of port P(DPL) specified with the immediate data t ₁ t ₀ is 1, a branch to the address specified with the immediate data P ₇ P ₆ P ₅ P ₄ P ₃ P ₂ P ₁ P ₀ within the same page occurs.		Mnemonic is BPI0 to BPI3 according to the value of t.
	BNPI addr	Branch on no Port bit	0 0 1 1	P ₇ P ₆ P ₅ P ₄	2 2	PC ₇ ~ 0 ← P ₇ P ₆ P ₅ P ₄ P ₃ P ₂ P ₁ P ₀ if (P(DPL, t ₁ t ₀)) = 0	If a single bit of port P(DPL) specified with the immediate data t ₁ t ₀ is 0, a branch to the address specified with the immediate data P ₇ P ₆ P ₅ P ₄ P ₃ P ₂ P ₁ P ₀ within the same page occurs.		Mnemonic is BNPI0 to BNPI3 according to the value of t.
	BTM addr	Branch on timer	0 1 1 1	P ₇ P ₆ P ₅ P ₄	2 2	PC ₇ ~ 0 ← P ₇ P ₆ P ₅ P ₄ P ₃ P ₂ P ₁ P ₀ if TMF = 1 then TMF ← 0	If the TMF is 1, a branch to the address specified with the immediate data P ₇ P ₆ P ₅ P ₄ P ₃ P ₂ P ₁ P ₀ within the same page occurs. The TMF is reset.	TMF	

LC6520C, 6520H, 6522C, 6522H

Instruction group	Mnemonic	Instruction code		Bytes	Cycles	Function	Description [*]	Status flag affected	Remarks
		D ₇ D ₆ D ₅ D ₄	D ₃ D ₂ D ₁ D ₀						
Branch instructions	BNTM addr	Branch on no timer	0 0 1 1 P ₇ P ₆ P ₅ P ₄	1 1 0 0 P ₃ P ₂ P ₁ P ₀	2	2	PC _{7~0} ← P ₇ P ₆ P ₅ P ₄ P ₃ P ₂ P ₁ P ₀ if TMF = 0 then TMF ← 0	If the TMF is 0, a branch to the address specified with the immediate data P ₇ P ₆ P ₅ P ₄ P ₃ P ₂ P ₁ P ₀ within the same page occurs. The TMF is reset.	TMF
	BI addr	Branch on interrupt	0 1 1 1 P ₇ P ₆ P ₅ P ₄	1 1 0 1 P ₃ P ₂ P ₁ P ₀	2	2	PC _{7~0} ← P ₇ P ₆ P ₅ P ₄ P ₃ P ₂ P ₁ P ₀ if EXTF = 1 then EXTF ← 0	If the EXTF is 1, a branch to the address specified with the immediate data P ₇ P ₆ P ₅ P ₄ P ₃ P ₂ P ₁ P ₀ within the same page occurs. The EXTF is reset.	EXTF
	BNI addr	Branch on no interrupt	0 0 1 1 P ₇ P ₆ P ₅ P ₄	1 1 0 1 P ₃ P ₂ P ₁ P ₀	2	2	PC _{7~0} ← P ₇ P ₆ P ₅ P ₄ P ₃ P ₂ P ₁ P ₀ if EXTF = 0 then EXTF ← 0	If the EXTF is 0, a branch to the address specified with the immediate data P ₇ P ₆ P ₅ P ₄ P ₃ P ₂ P ₁ P ₀ within the same page occurs. The EXTF is reset.	EXTF
	BC addr	Branch on CF	0 1 1 1 P ₇ P ₆ P ₅ P ₄	1 1 1 1 P ₃ P ₂ P ₁ P ₀	2	2	PC _{7~0} ← P ₇ P ₆ P ₅ P ₄ P ₃ P ₂ P ₁ P ₀ if CF = 1	If the CF is 1, a branch to the address specified with the immediate data P ₇ P ₆ P ₅ P ₄ P ₃ P ₂ P ₁ P ₀ within the same page occurs.	
	BNC addr	Branch on no CF	0 0 1 1 P ₇ P ₆ P ₅ P ₄	1 1 1 1 P ₃ P ₂ P ₁ P ₀	2	2	PC _{7~0} ← P ₇ P ₆ P ₅ P ₄ P ₃ P ₂ P ₁ P ₀ if CF = 0	If the CF is 0, a branch to the address specified with the immediate data P ₇ P ₆ P ₅ P ₄ P ₃ P ₂ P ₁ P ₀ within the same page occurs.	
	BZ addr	Branch on ZF	0 1 1 1 P ₇ P ₆ P ₅ P ₄	1 1 1 0 P ₃ P ₂ P ₁ P ₀	2	2	PC _{7~0} ← P ₇ P ₆ P ₅ P ₄ P ₃ P ₂ P ₁ P ₀ if ZF = 1	If the ZF is 1, a branch to the address specified with the immediate data P ₇ P ₆ P ₅ P ₄ P ₃ P ₂ P ₁ P ₀ within the same page occurs.	
	BNZ addr	Branch on no ZF	0 0 1 1 P ₇ P ₆ P ₅ P ₄	1 1 1 0 P ₃ P ₂ P ₁ P ₀	2	2	PC _{7~0} ← P ₇ P ₆ P ₅ P ₄ P ₃ P ₂ P ₁ P ₀ if ZF = 0	If the ZF is 0, a branch to the address specified with the immediate data P ₇ P ₆ P ₅ P ₄ P ₃ P ₂ P ₁ P ₀ within the same page occurs.	
	BF _n addr	Branch on flag bit	1 1 0 1 P ₇ P ₆ P ₅ P ₄	n ₃ n ₂ n ₁ n ₀ P ₃ P ₂ P ₁ P ₀	2	2	PC _{7~0} ← P ₇ P ₆ P ₅ P ₄ P ₃ P ₂ P ₁ P ₀ if F _n = 1	If the flag bit of the 16 flags specified with the immediate data n ₃ n ₂ n ₁ n ₀ is 1, a branch to the address specified with the immediate data P ₇ P ₆ P ₅ P ₄ P ₃ P ₂ P ₁ P ₀ within the same page occurs.	Mnemonic is BF _n to BF15 according to the value of n.
	BNF _n addr	Branch on no flag bit	1 0 0 1 P ₇ P ₆ P ₅ P ₄	n ₃ n ₂ n ₁ n ₀ P ₃ P ₂ P ₁ P ₀	2	2	PC _{7~0} ← P ₇ P ₆ P ₅ P ₄ P ₃ P ₂ P ₁ P ₀ if F _n = 0	If the flag bit of the 16 flags specified with the immediate data n ₃ n ₂ n ₁ n ₀ is 0, a branch to the address specified with the immediate data P ₇ P ₆ P ₅ P ₄ P ₃ P ₂ P ₁ P ₀ within the same page occurs.	Mnemonic is BNF _n to BNF15 according to the value of n.
Input/Output instructions	IP	Input port to AC	0 0 0 0	1 1 0 0	1	1	AC ← (P ₁ DP ₁)	Port P ₁ DP ₁ contents are loaded in the AC.	ZF
	OP	Output AC to port	0 1 1 0	0 0 0 1	1	1	P ₁ DP ₁ ← (AC)	The AC contents are outputted to port P ₁ DP ₁ .	
	SPB bit	Set port bit	0 0 0 0	0 1 B ₁ B ₀	1	2	P ₁ DP ₁ B ₁ B ₀ ← 1	A single bit in port P ₁ DP ₁ specified with the immediate data B ₁ B ₀ is set.	When this instruction is executed, the E contents are destroyed.
	RPB bit	Reset port bit	0 0 1 0	0 1 B ₁ B ₀	1	2	P ₁ DP ₁ B ₁ B ₀ ← 0	A single bit in port P ₁ DP ₁ specified with the immediate data B ₁ B ₀ is reset.	ZF When this instruction is executed, the E contents are destroyed.
Other instructions	SCTL bit	Set control register bit(S)	0 0 1 0 1 0 0 0	1 1 0 0 B ₃ B ₂ B ₁ B ₀	2	2	CTL ← CTL ₁ V B ₃ B ₂ B ₁ B ₀	The bits of the control register specified with the immediate data B ₃ B ₂ B ₁ B ₀ are set.	
	RCTL bit	Reset control register bit(S)	0 0 1 0 1 0 0 1	1 1 0 0 B ₃ B ₂ B ₁ B ₀	2	2	CTL ← CTL ₁ A B ₃ B ₂ B ₁ B ₀	The bits of the control register specified with the immediate data B ₃ B ₂ B ₁ B ₀ are reset.	ZF
	WTM	Write timer	1 1 1 1	1 0 0 1	1	1	TM ← (E), (AC) TMF ← 0	The E and AC contents are loaded in the timer. The TMF is reset.	TMF
	HALT	Halt	1 1 1 1	0 1 1 0	1	1	Halt	All operations stop.	Only when all pins of port PA are set at L, stop.
	NOP	No operation	0 0 0 0	0 0 0 0	1	1	No operation	No operation is performed, but 1 machine cycle is consumed.	

*1 If the CLA instruction is used consecutively in such a manner as CLA, CLA, ———, the first CLA instruction only is effective and the following CLA instructions are changed to the NOP instructions. This is also true of the LI instruction.

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